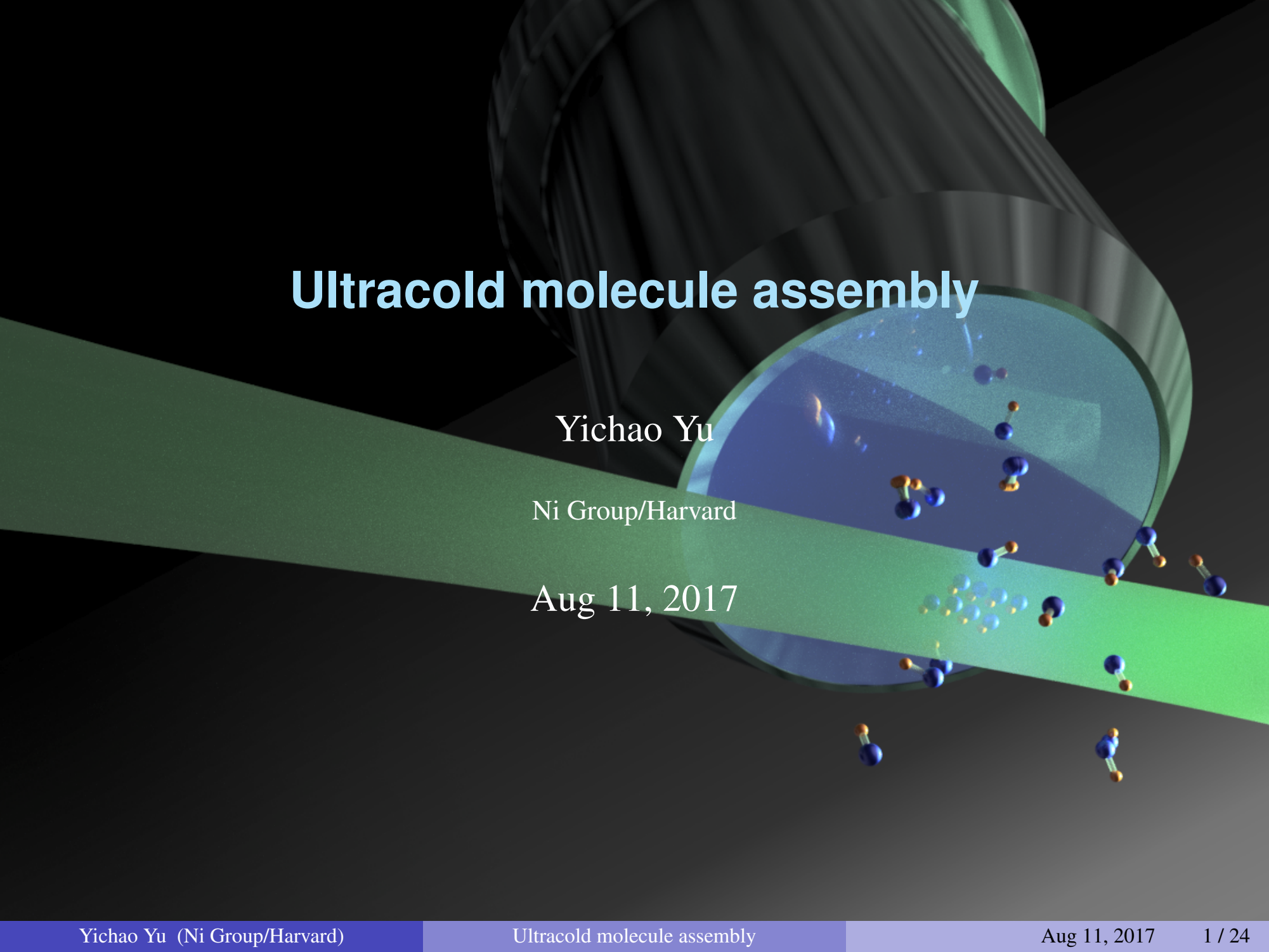


Ultracold molecule assembly

Yichao Yu

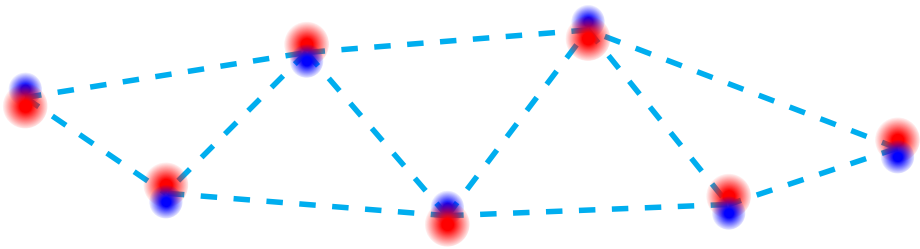
Ni Group/Harvard

Aug 11, 2017

Molecules in optical tweezer

Features

- Strong and tunable interaction
- Rich internal energy levels
- High filling fraction
- Single site detection and manipulation



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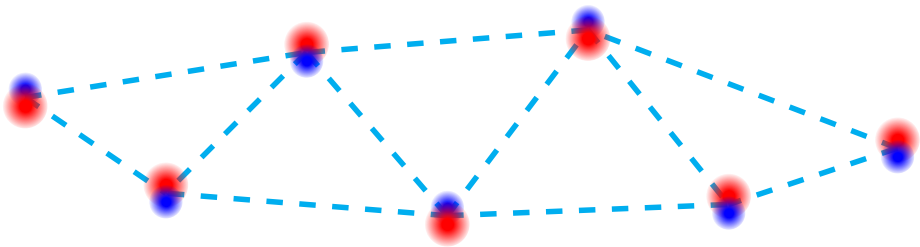

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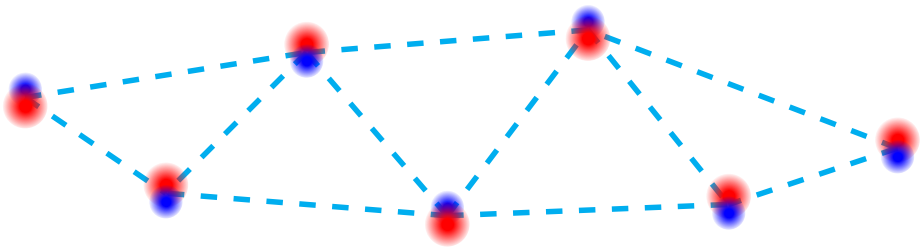

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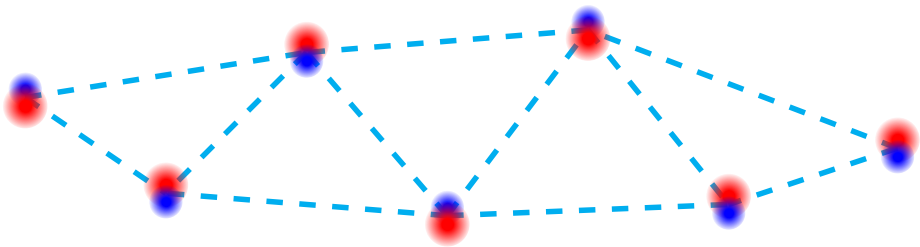

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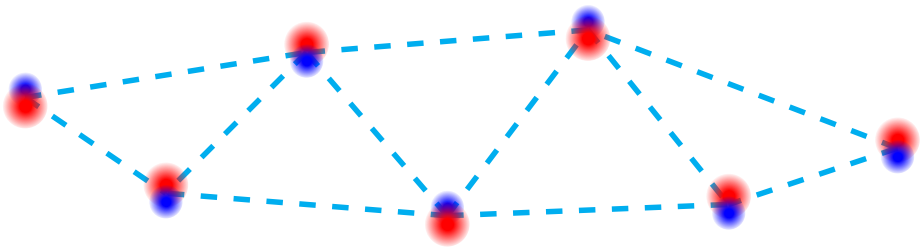
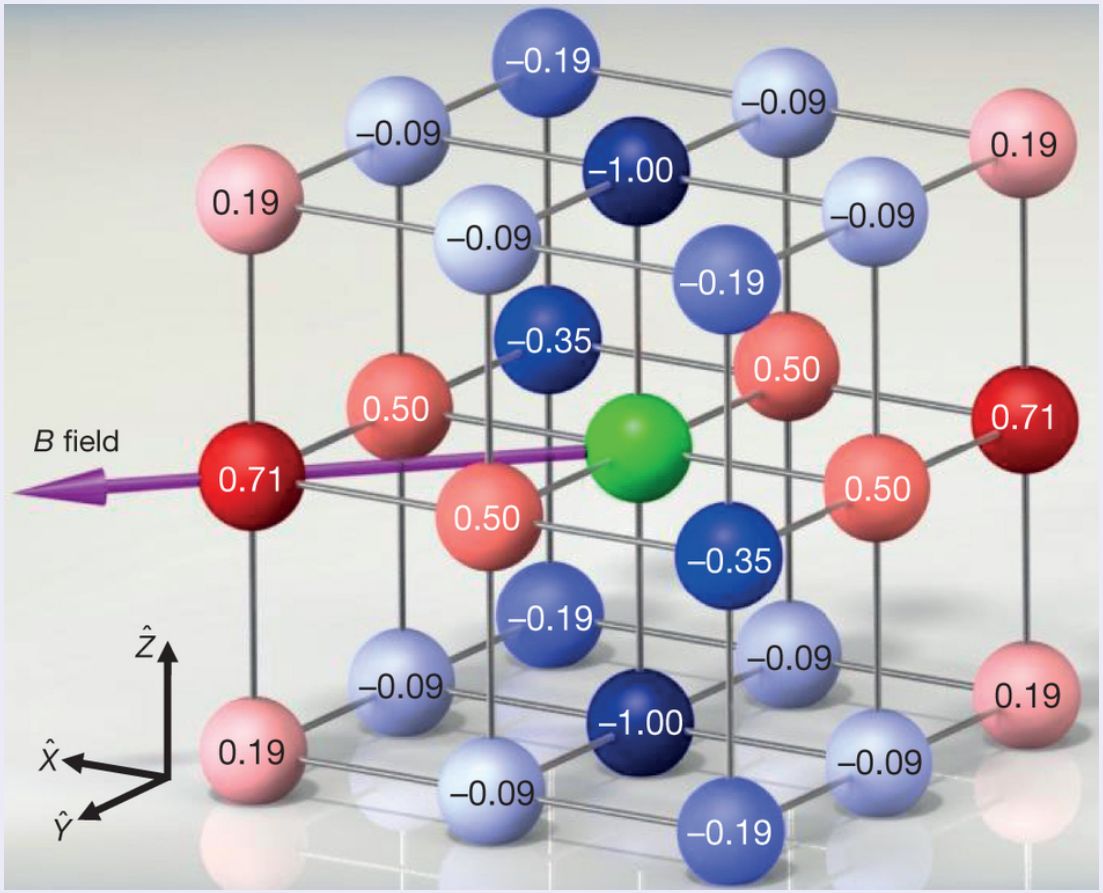


Applications

Simulation of many-body system[1]

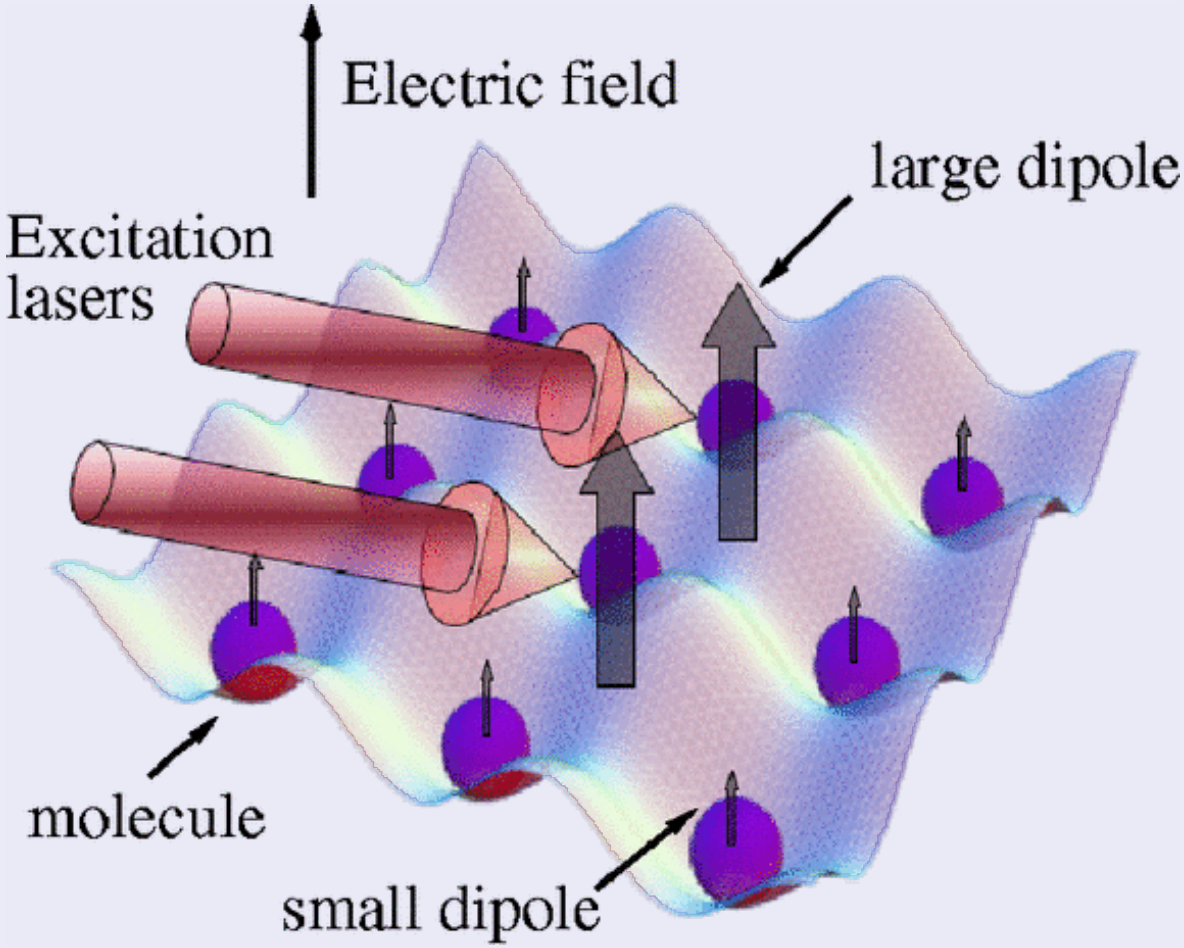


$$H \propto \sum V_{ij}\left(S_i^+ S_j^- + S_i^- S_j^+\right)$$

[1] B. Yan et al., "Observation of dipolar spin-exchange interactions with lattice-confined polar molecules.", Nature **501**, 521–5 (2013).

Applications

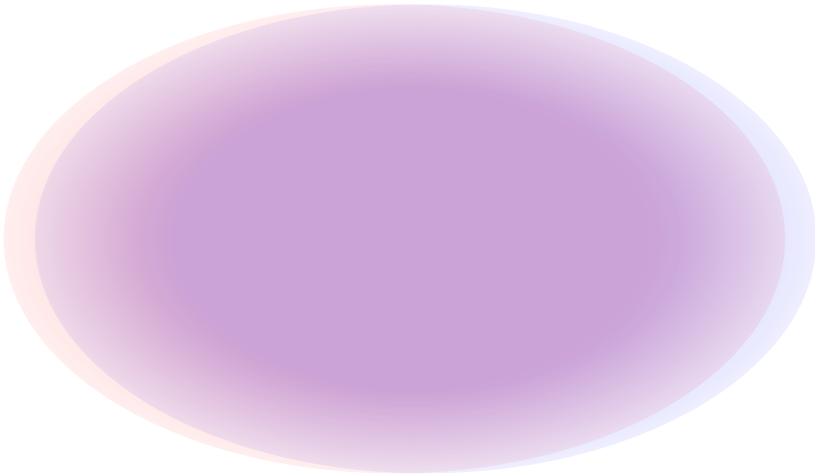
Quantum computation[2]



[2] S. F. Yelin et al., "Schemes for robust quantum computation with polar molecules", Phys. Rev. A **74**, 050301 (2006).

Making molecules from atoms

- MOT (Na + Cs)
- Loading single atoms
- Raman sideband cooling
- Merge traps
- Make molecules!



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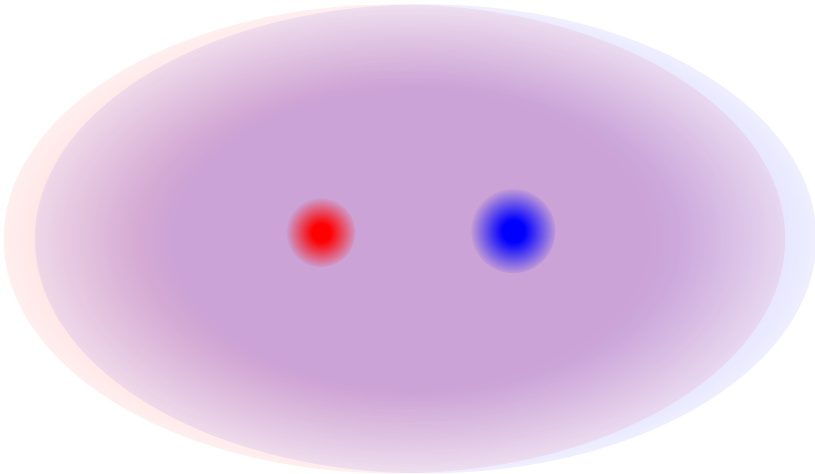

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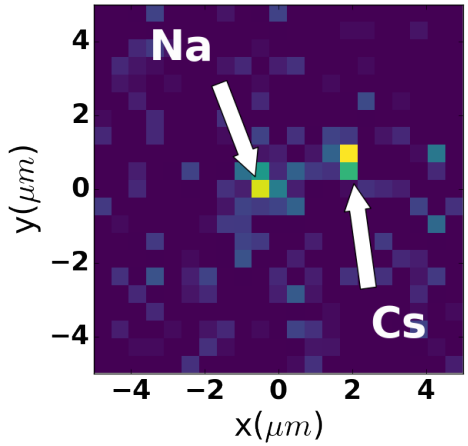
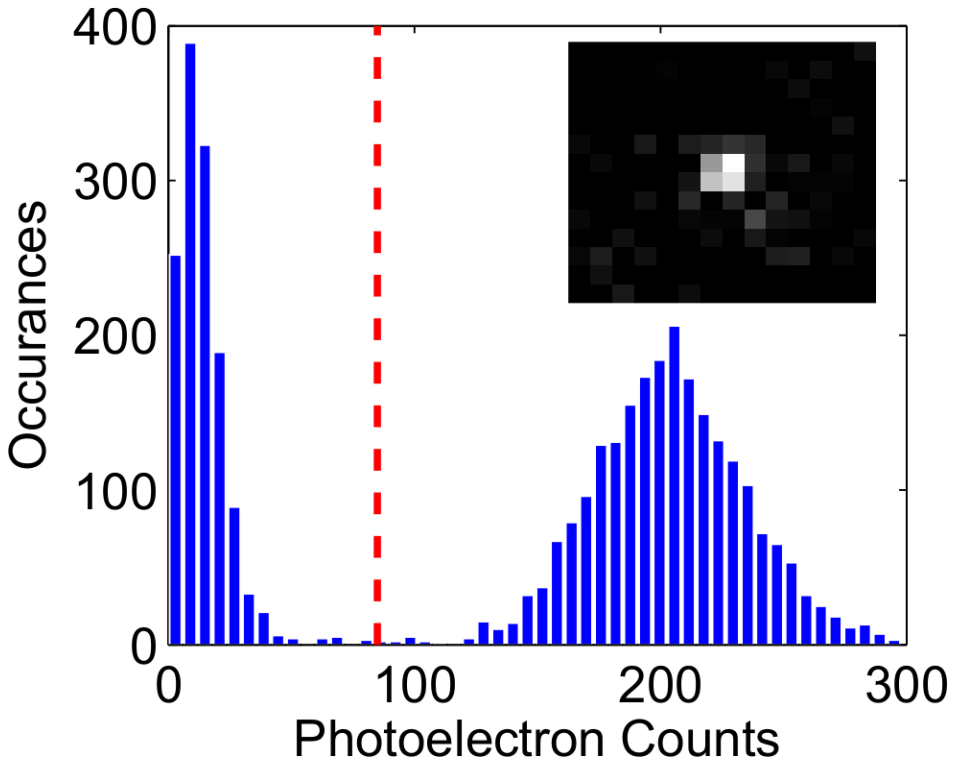


- Single atoms
- 85% ground state after Cesium Raman sideband cooling



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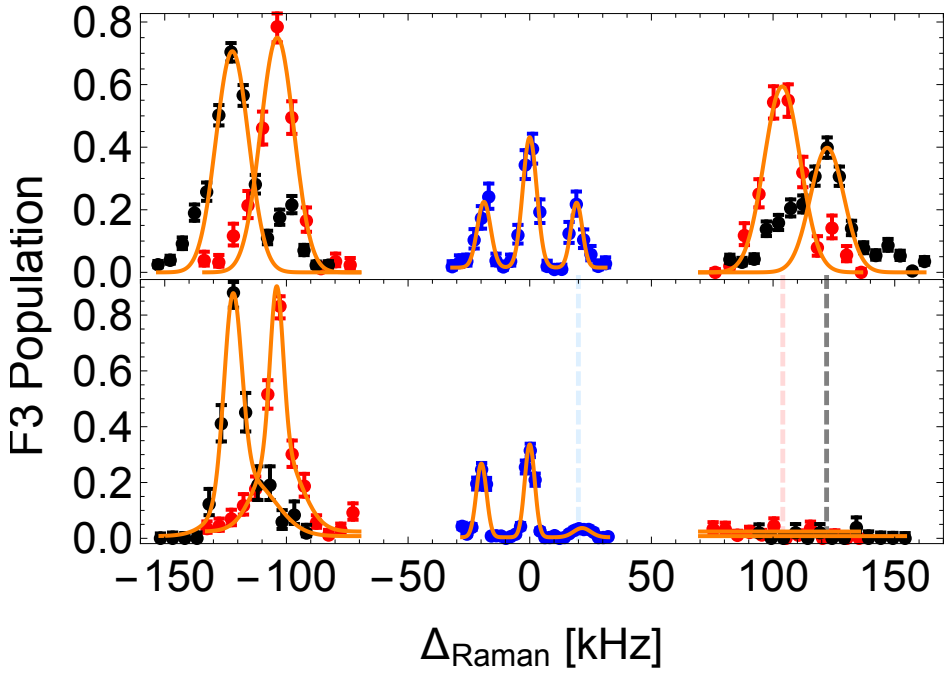

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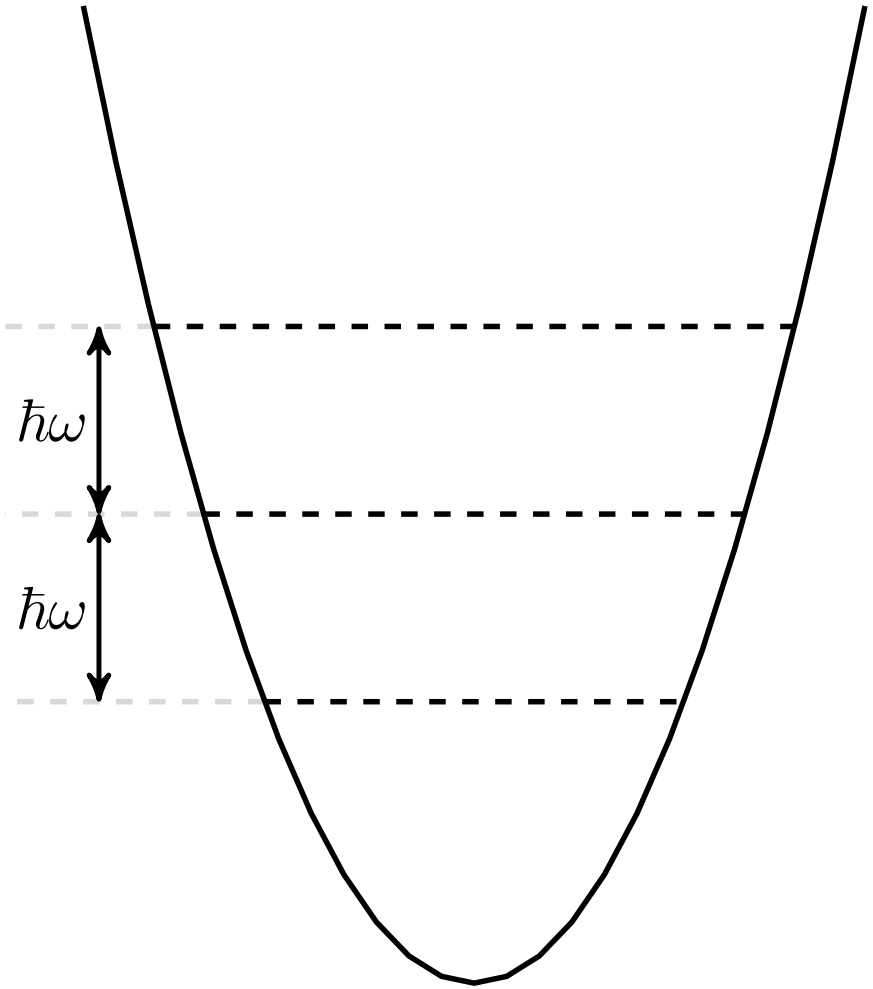

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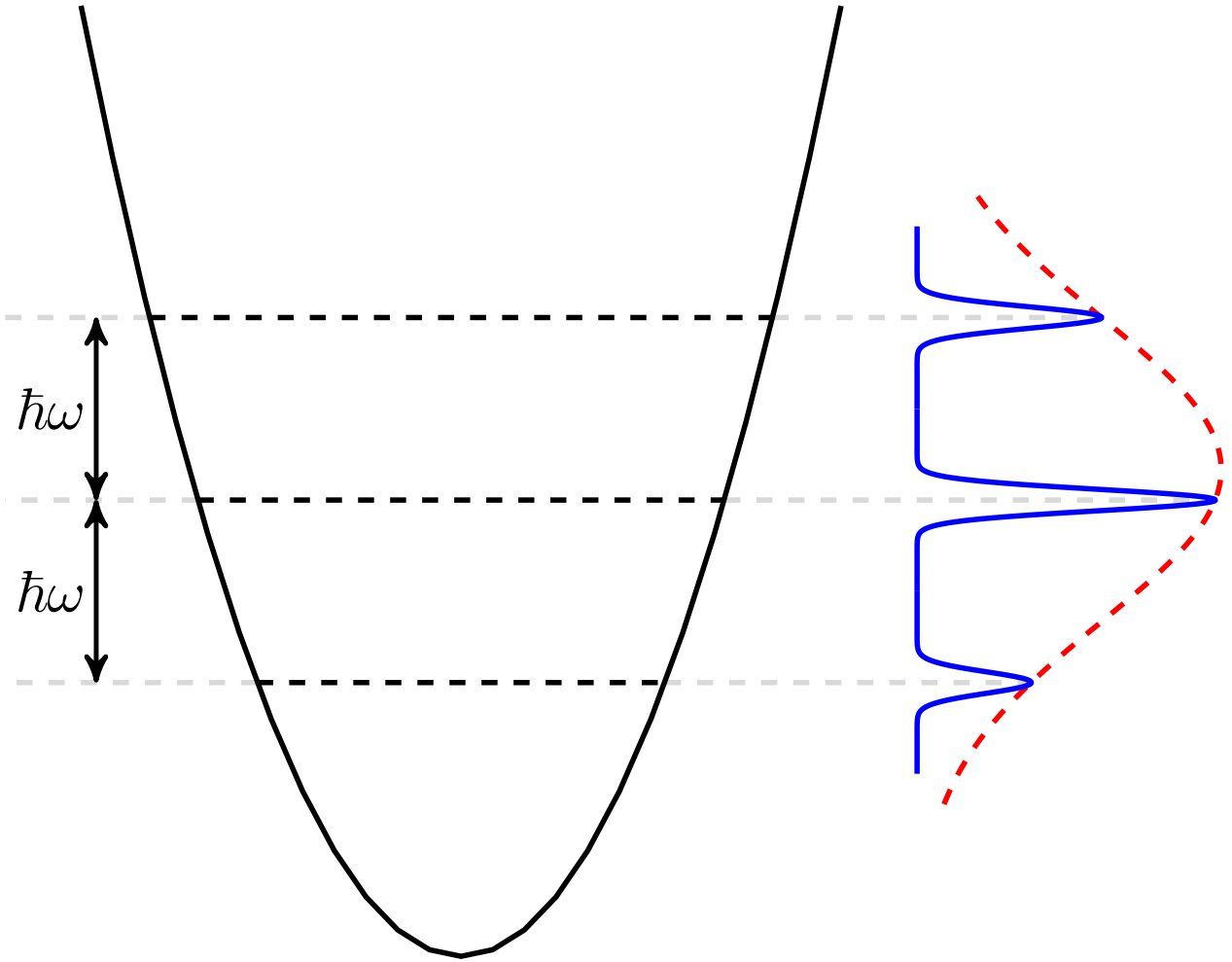

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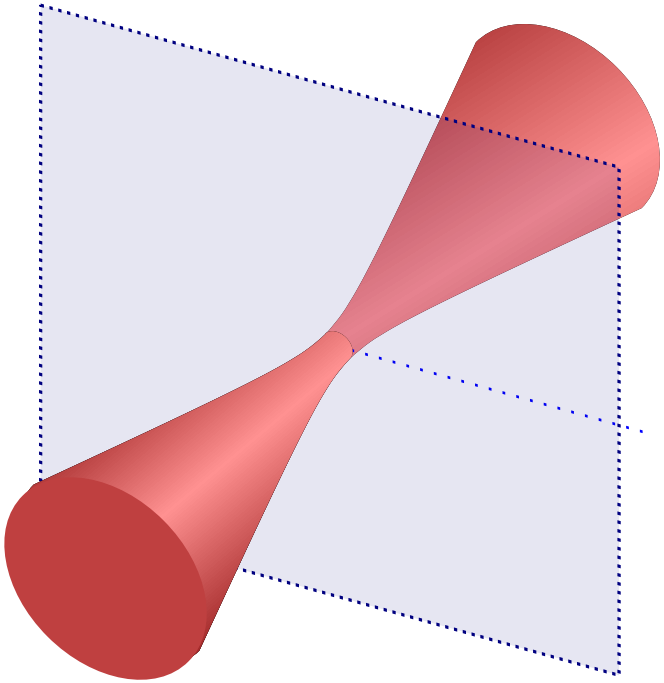

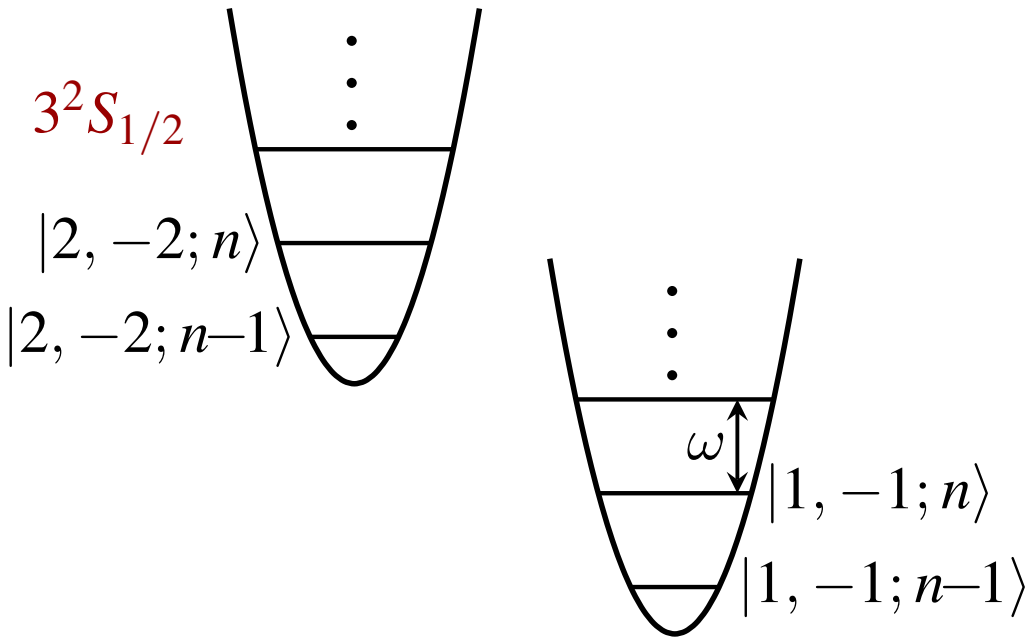

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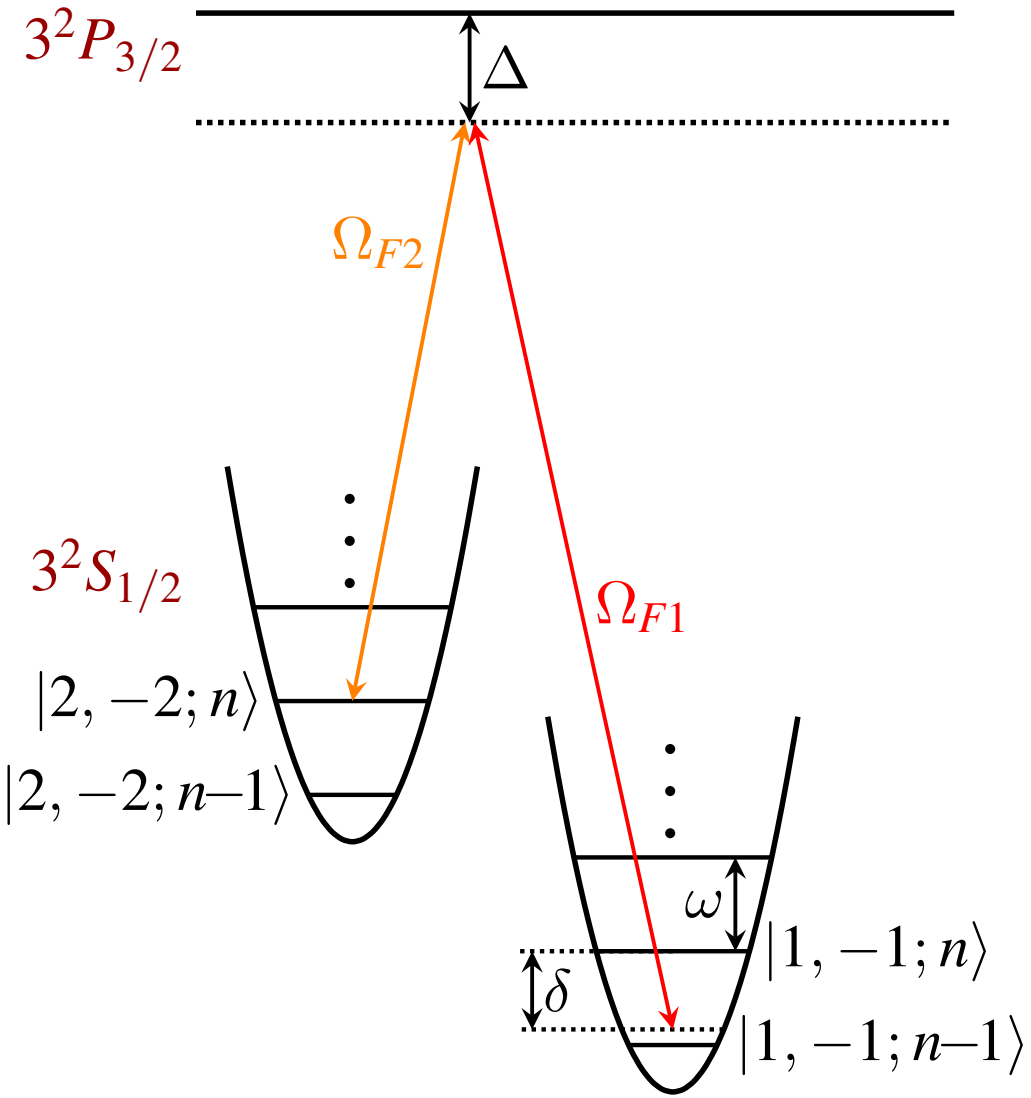

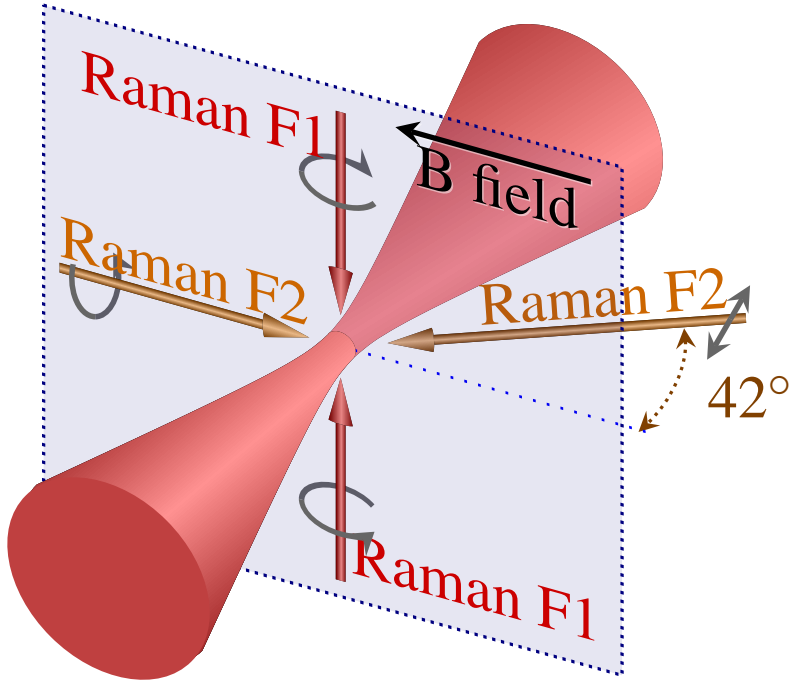

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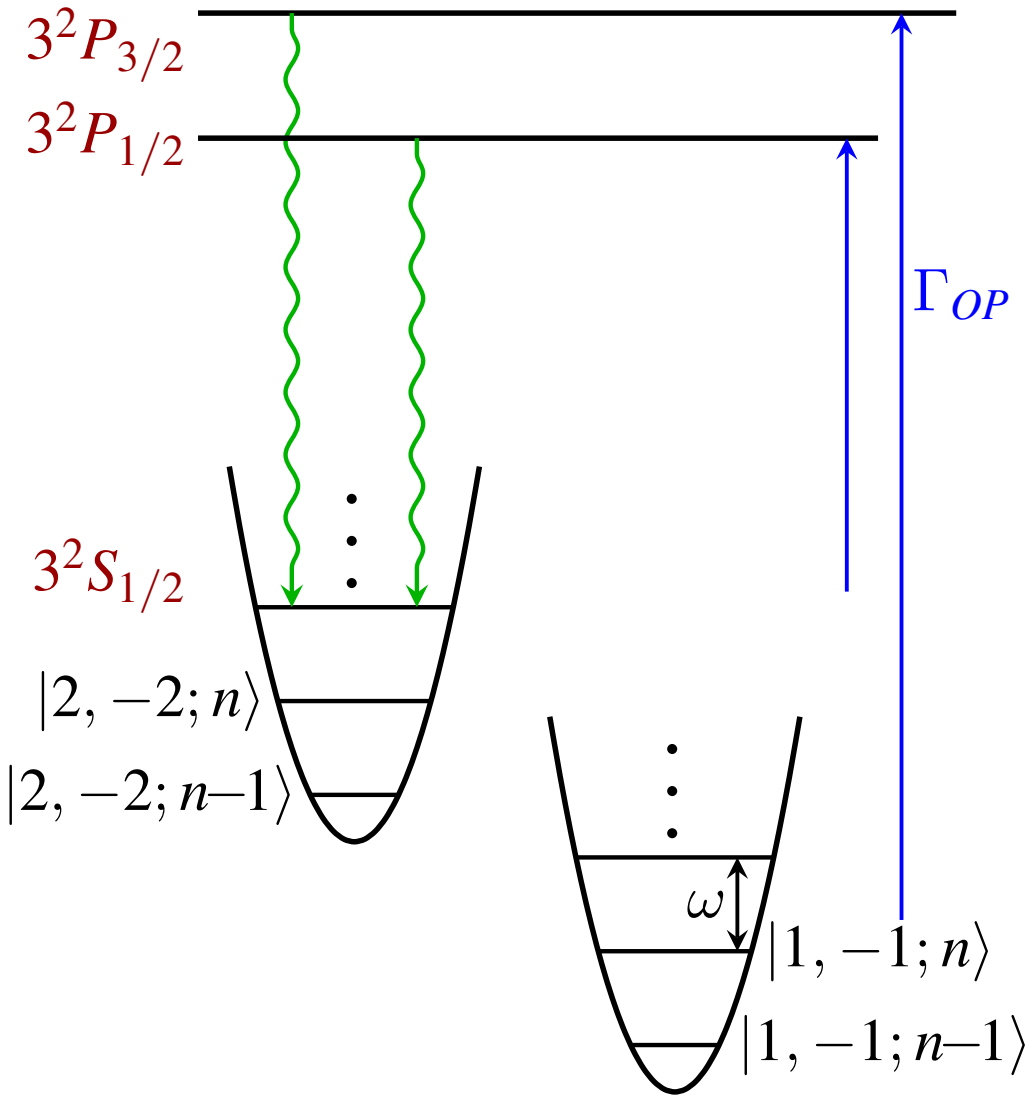

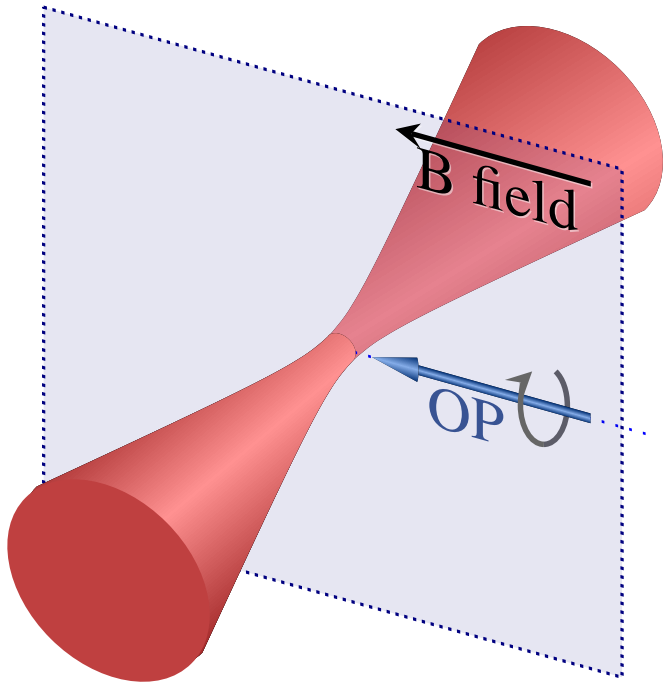

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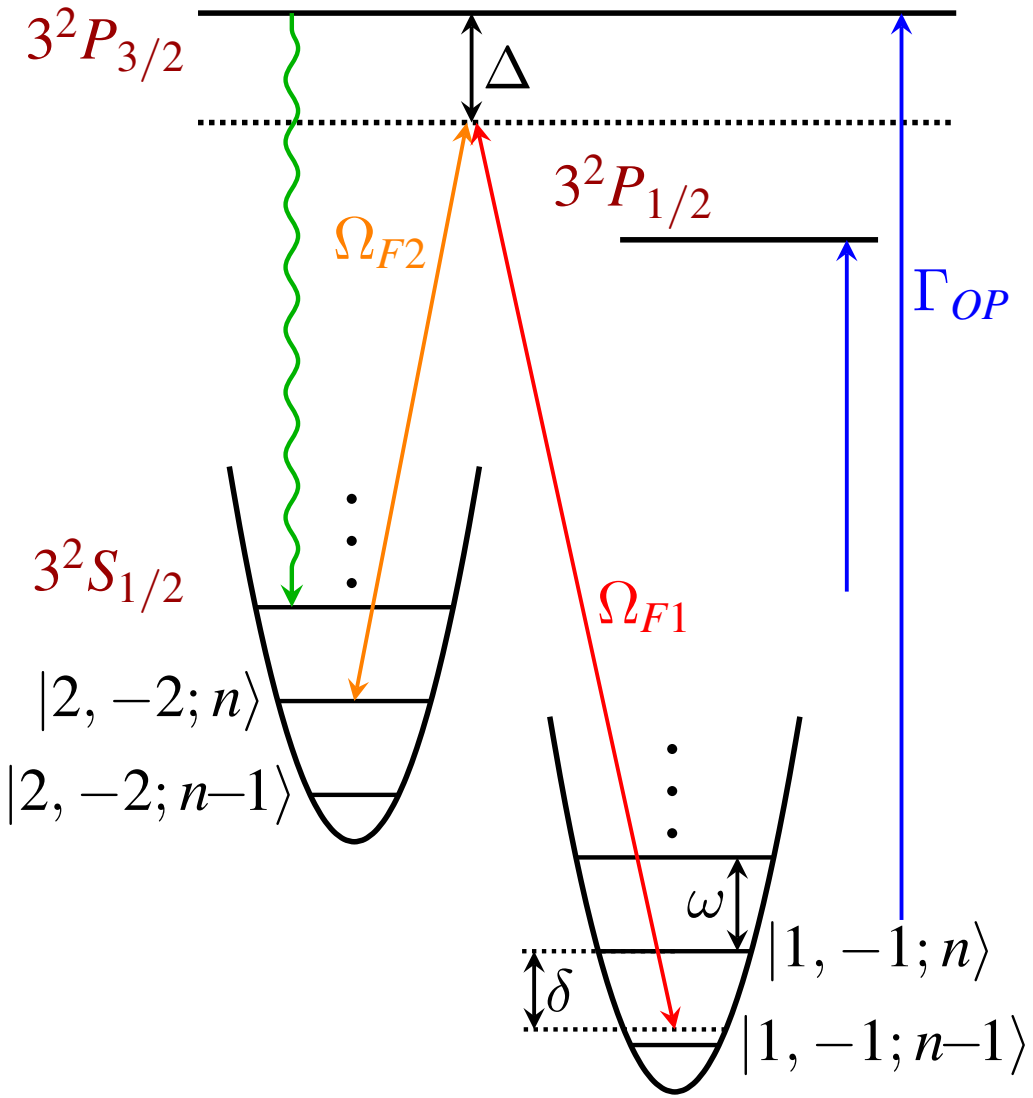

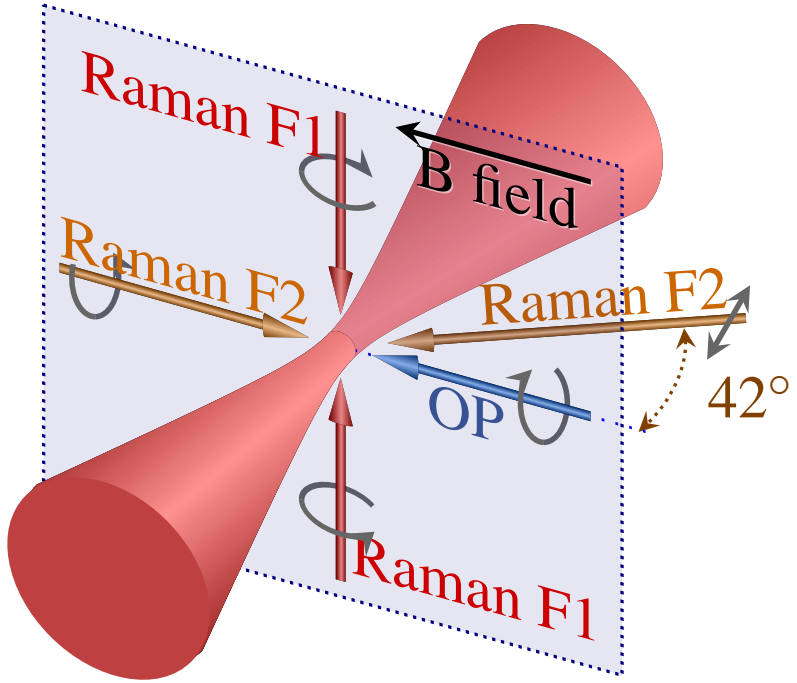

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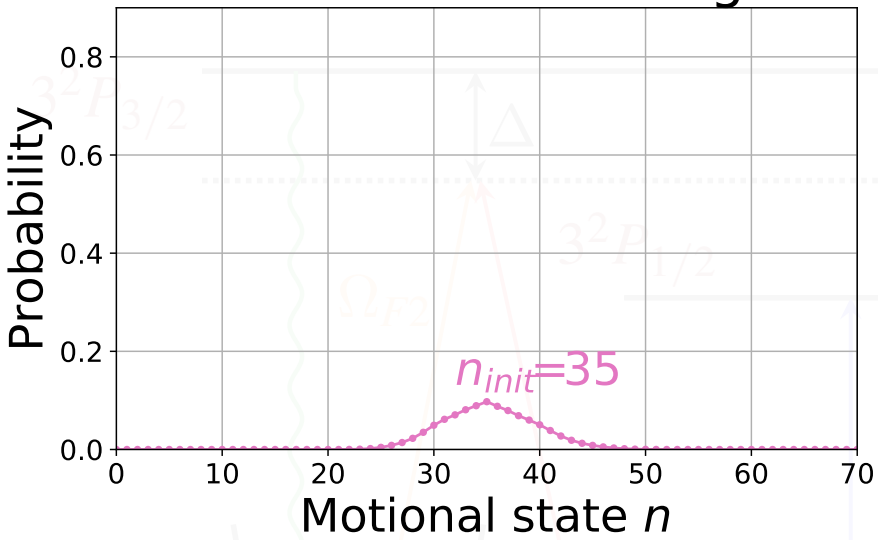
- Large light shift
- Trap anharmonicity
- Off resonance scattering $\approx 3 \sim 15$kHz

Motional state branching ratios



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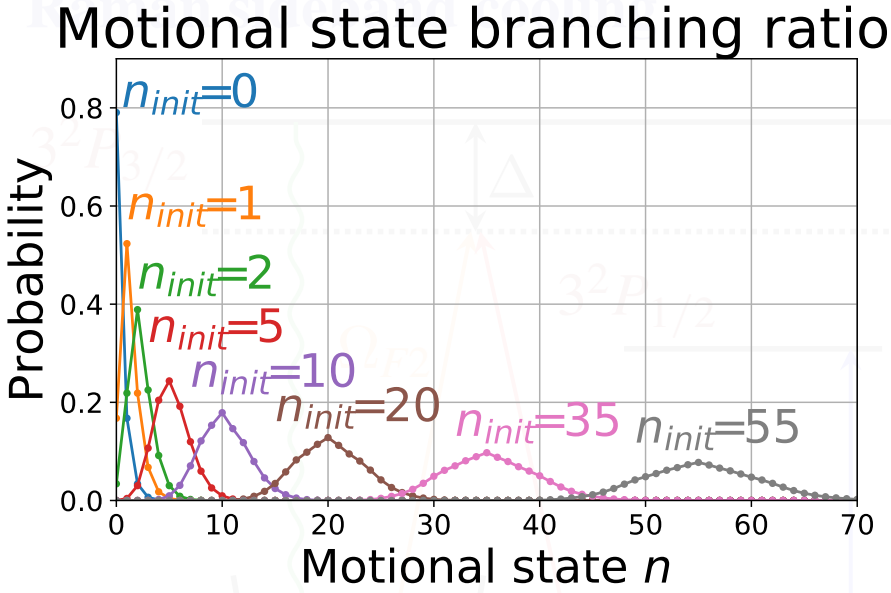

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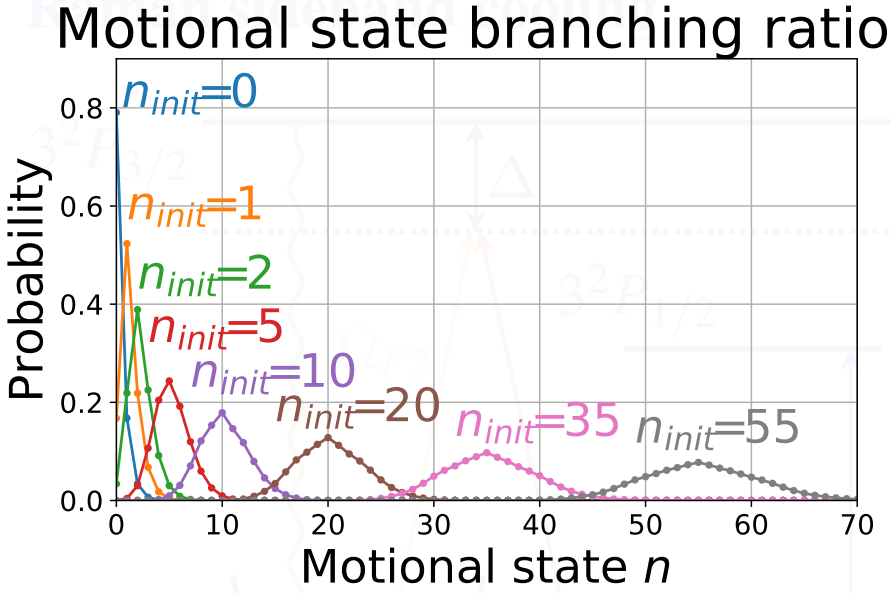

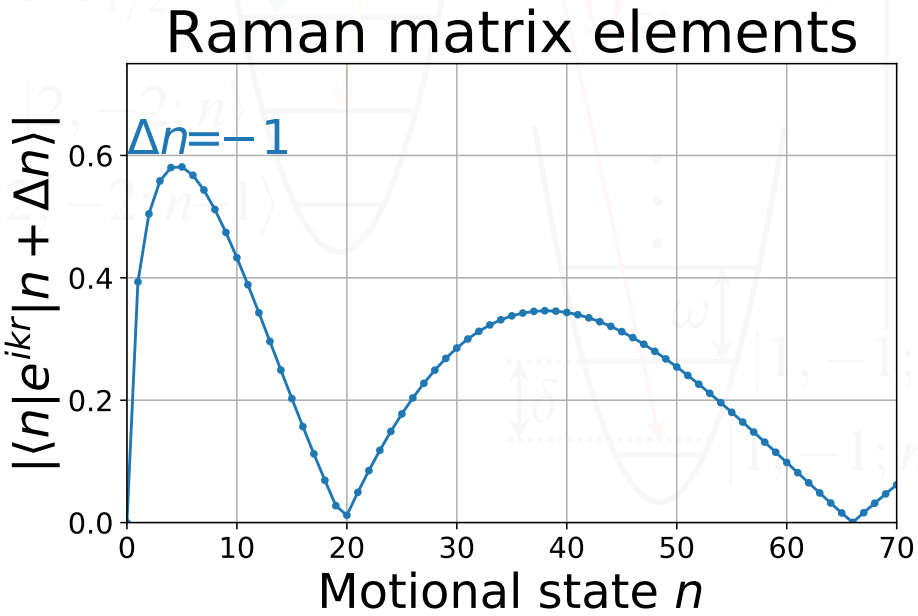

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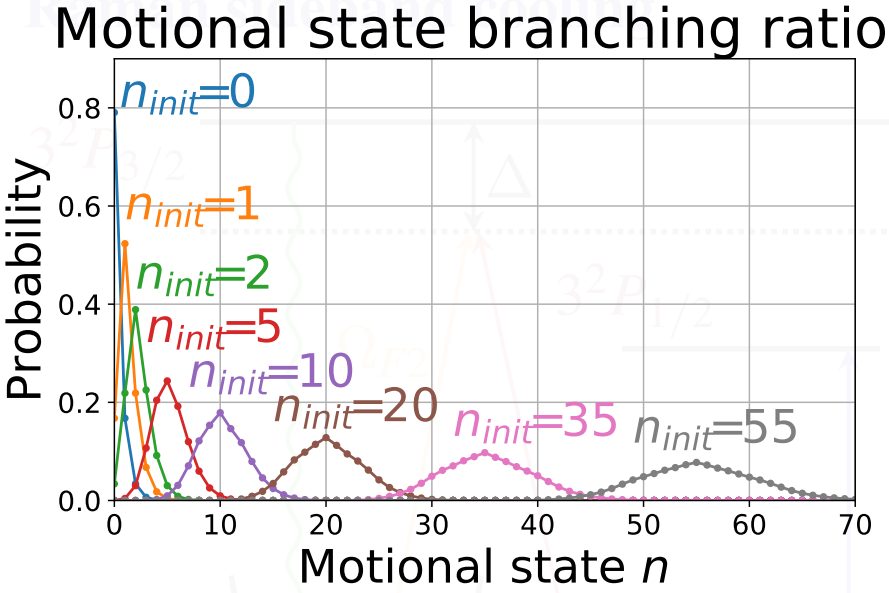

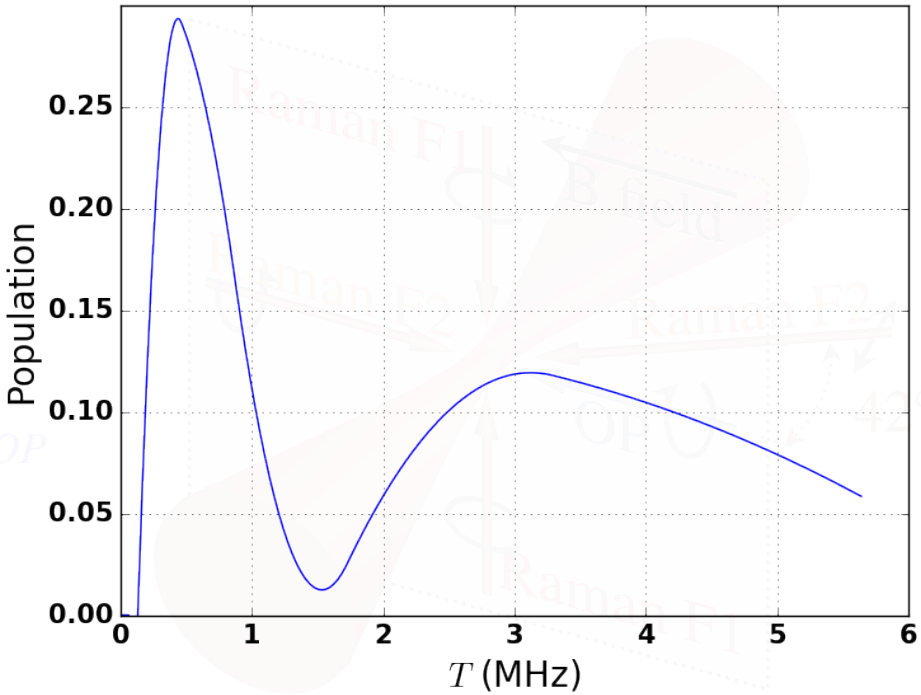

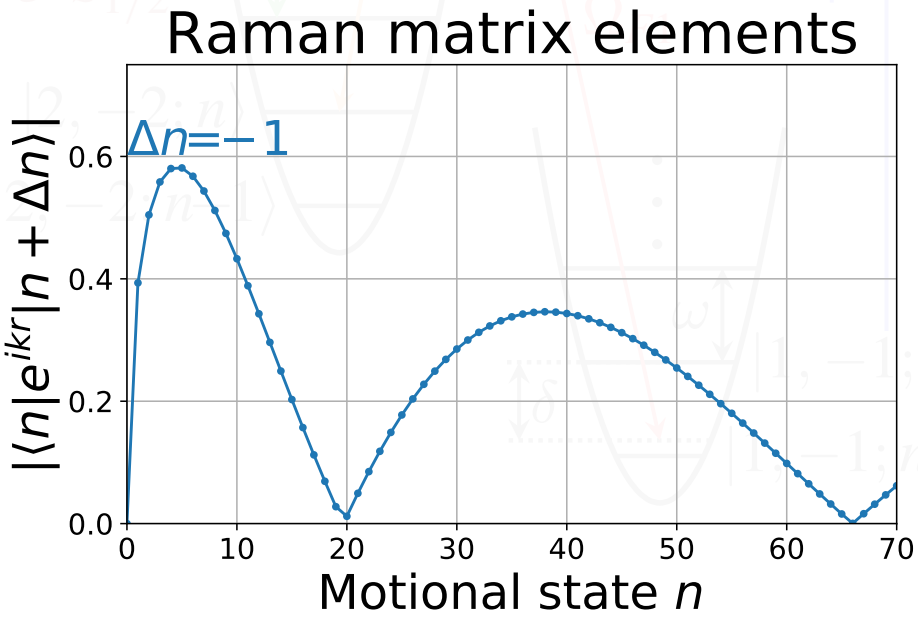

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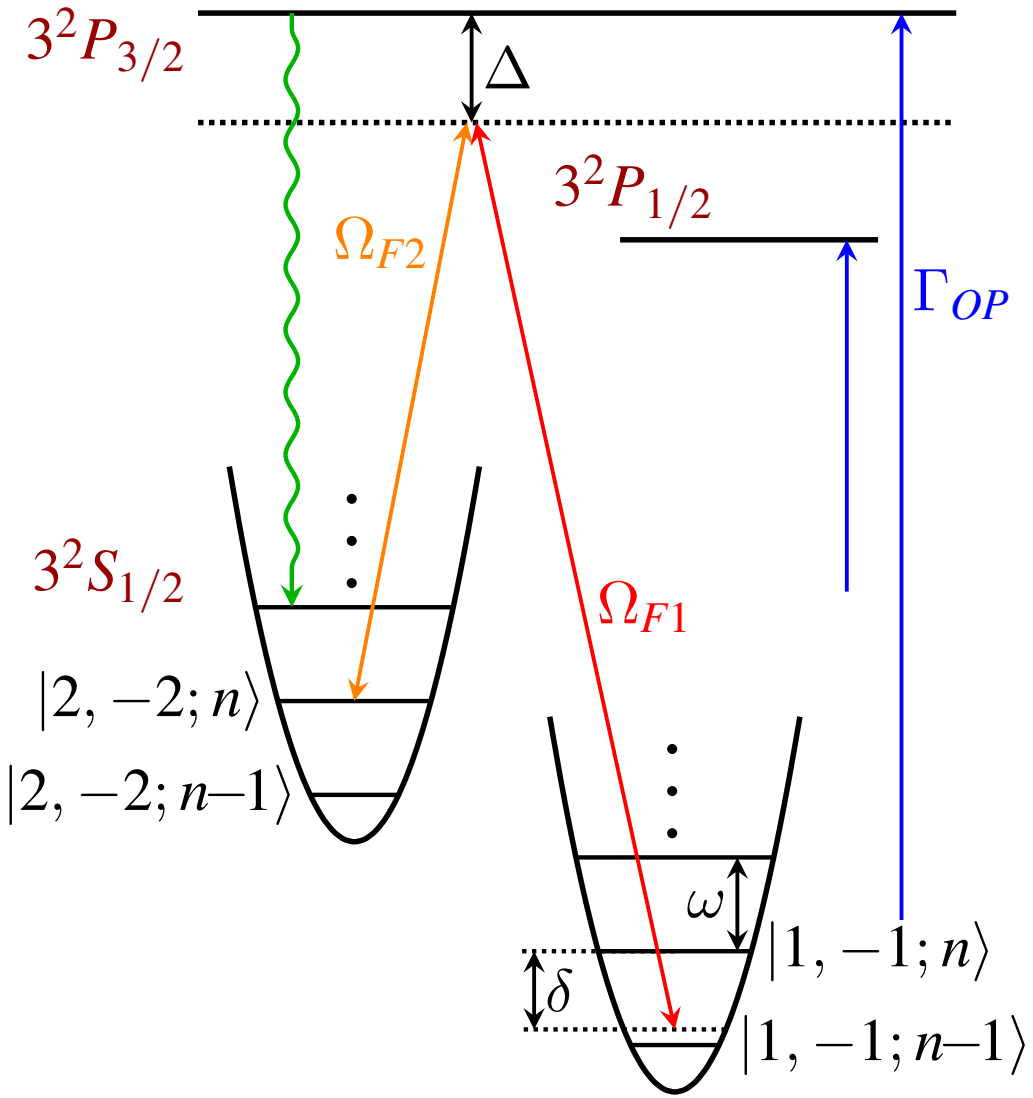

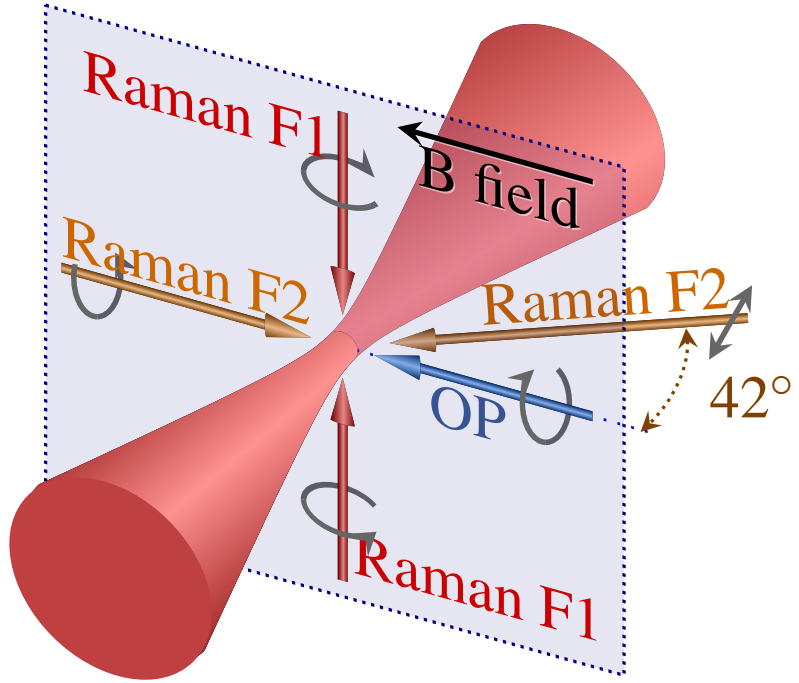

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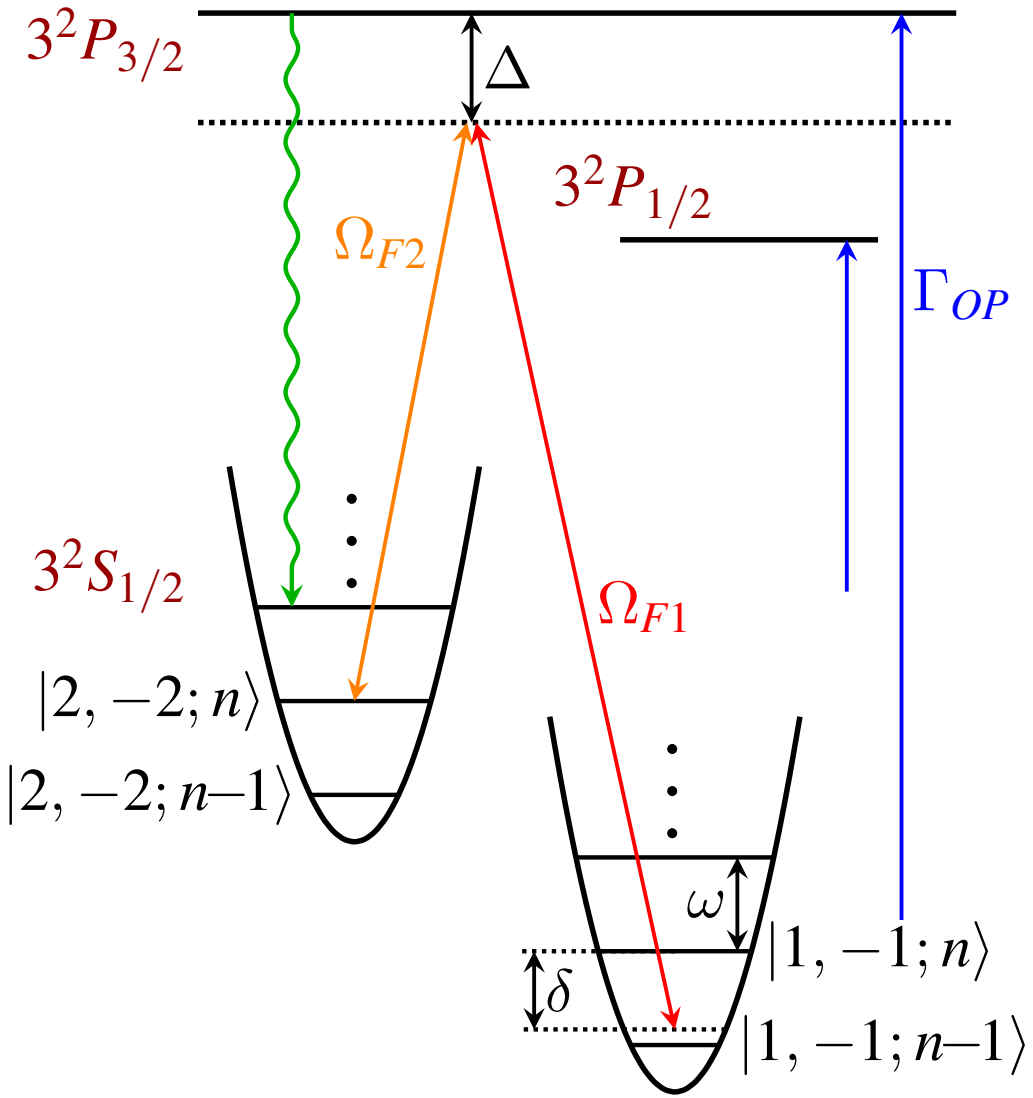

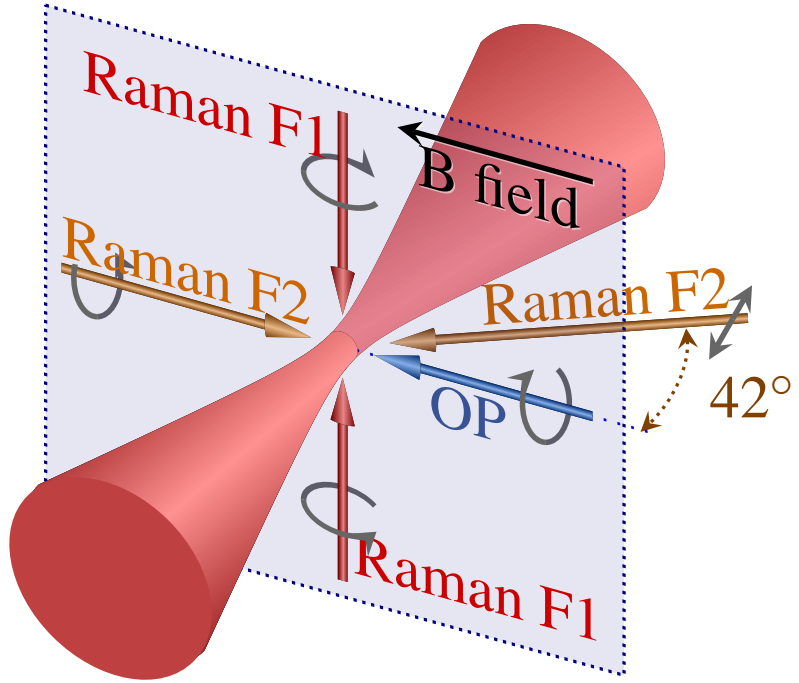

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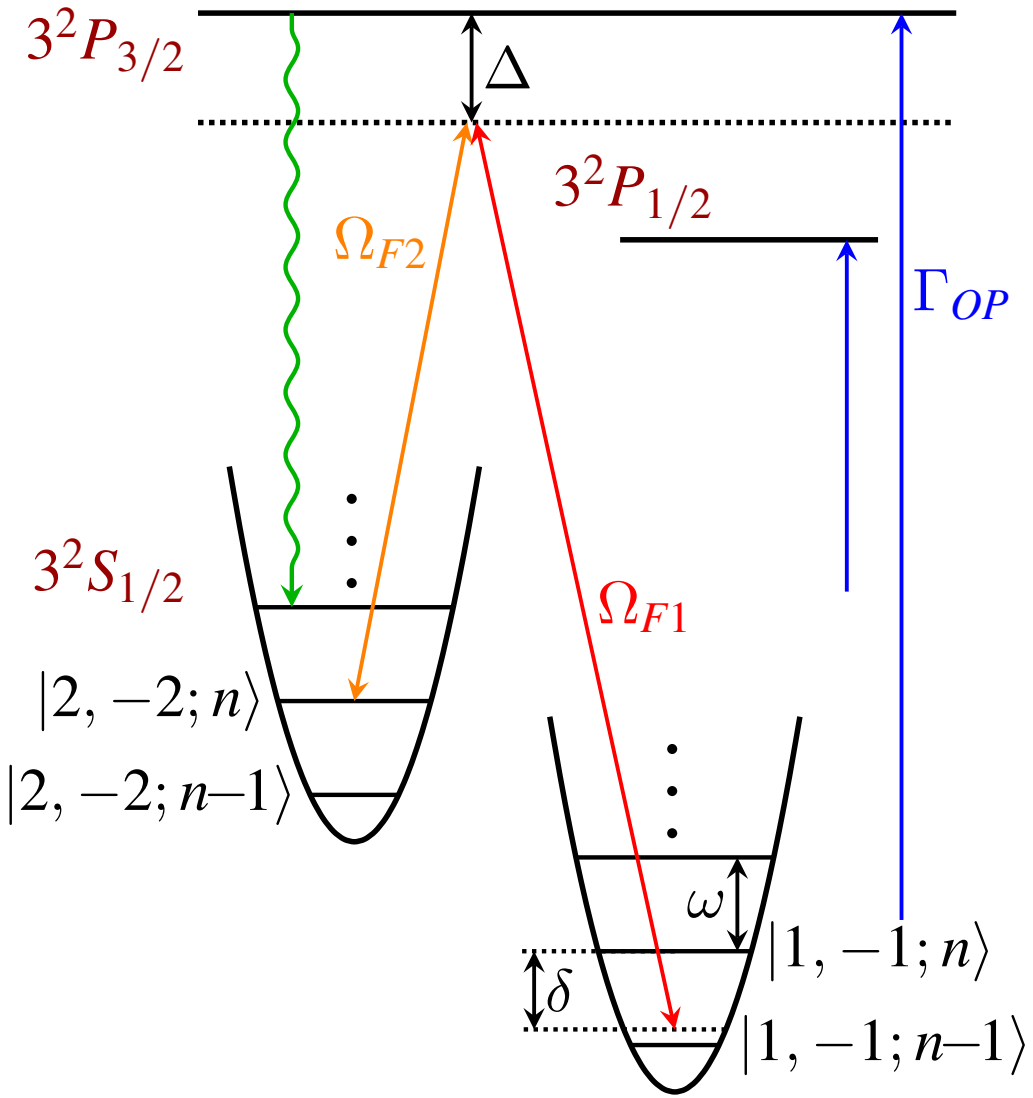

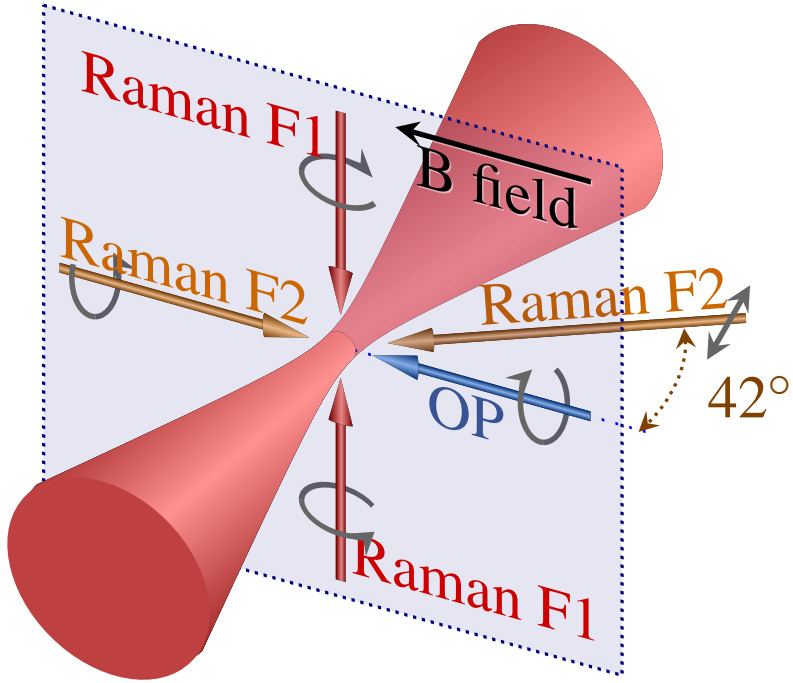

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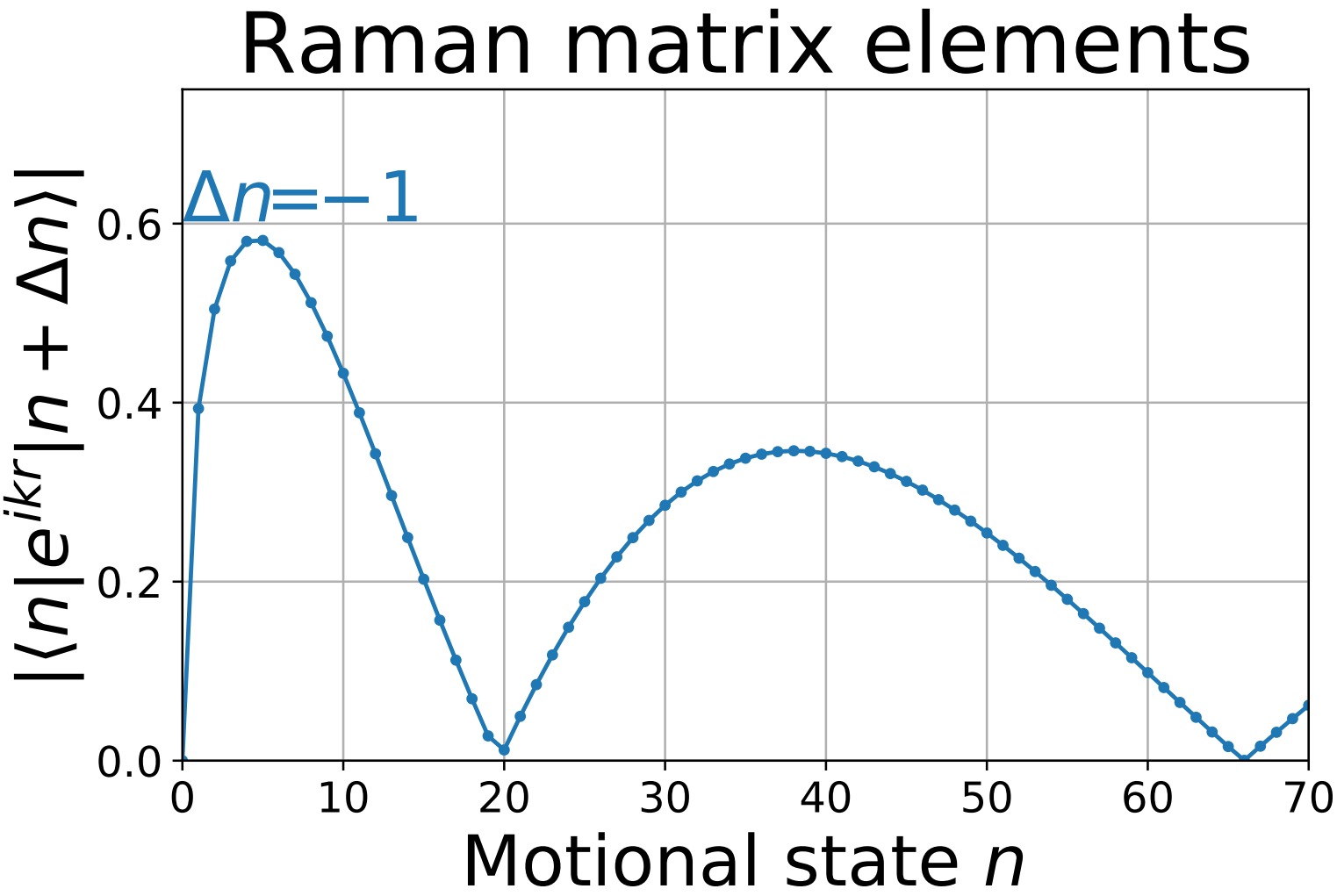

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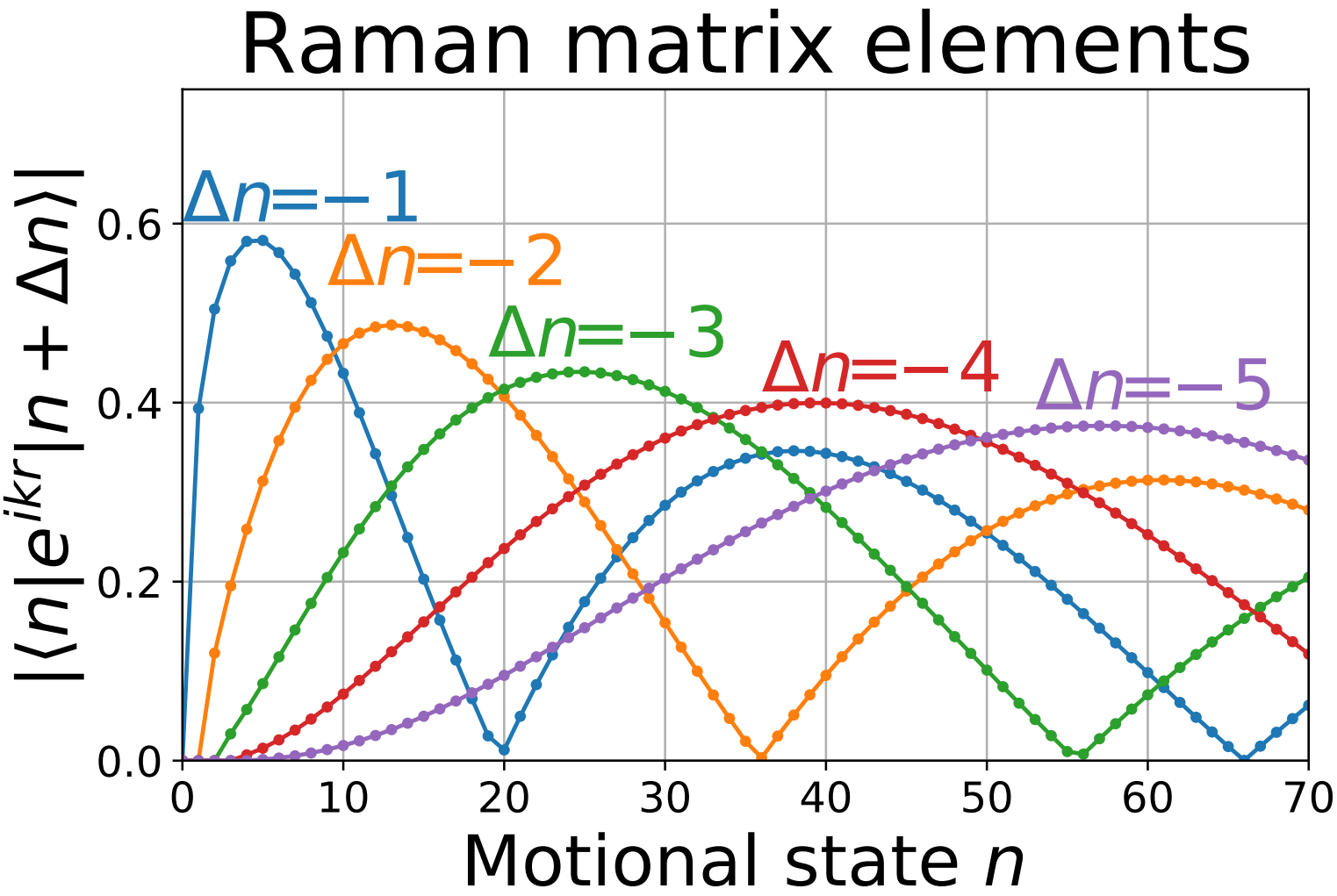

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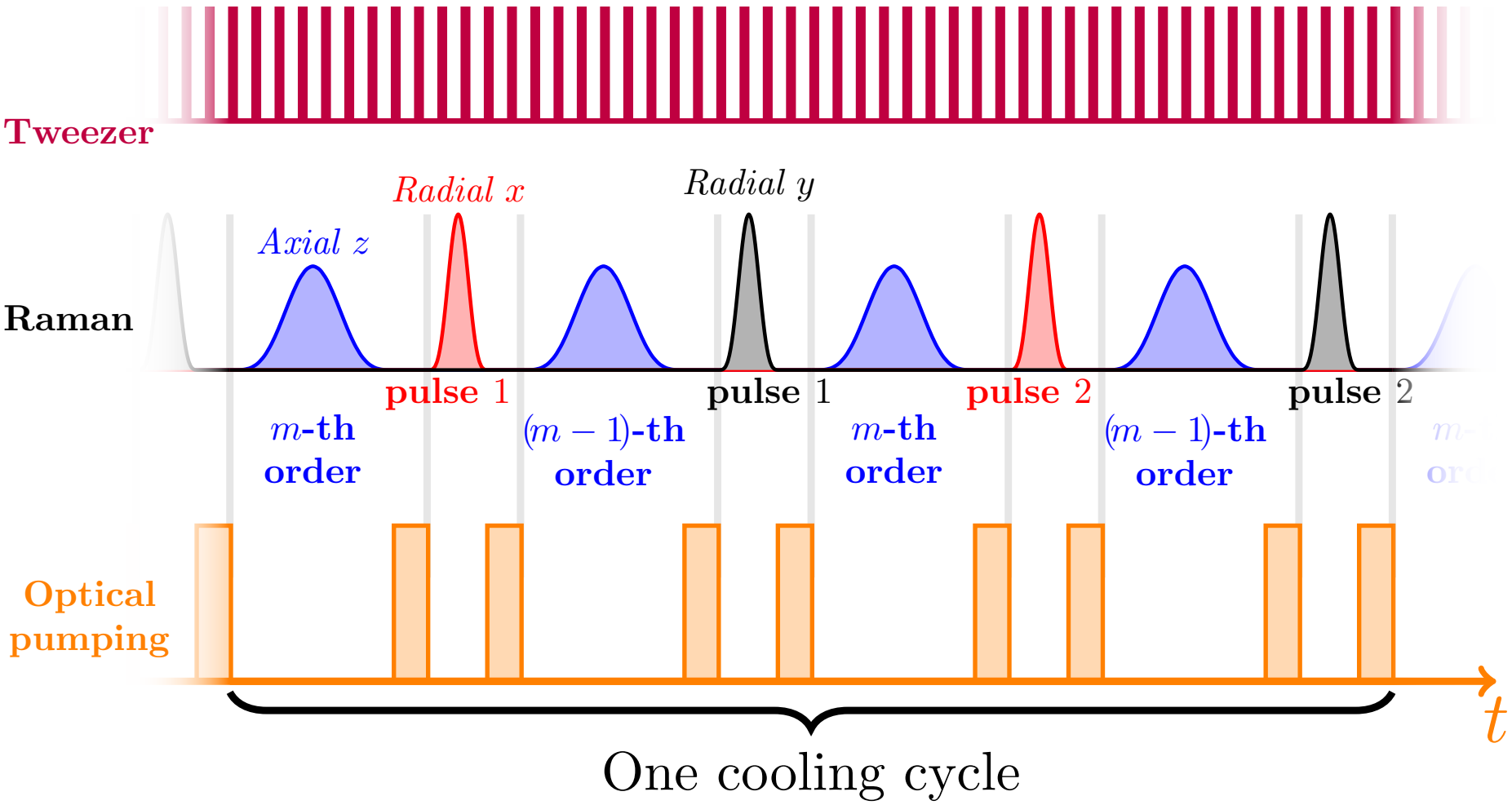

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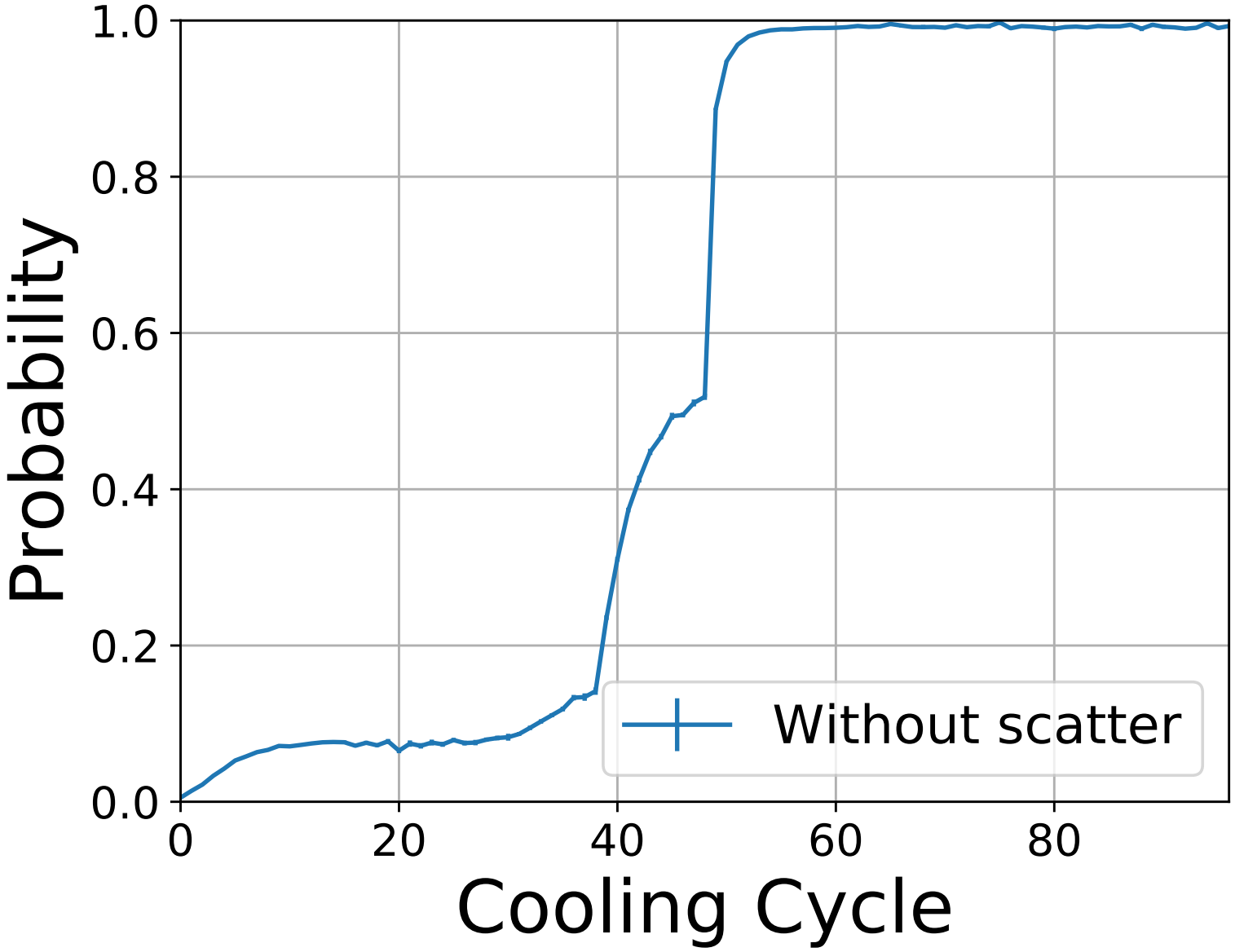

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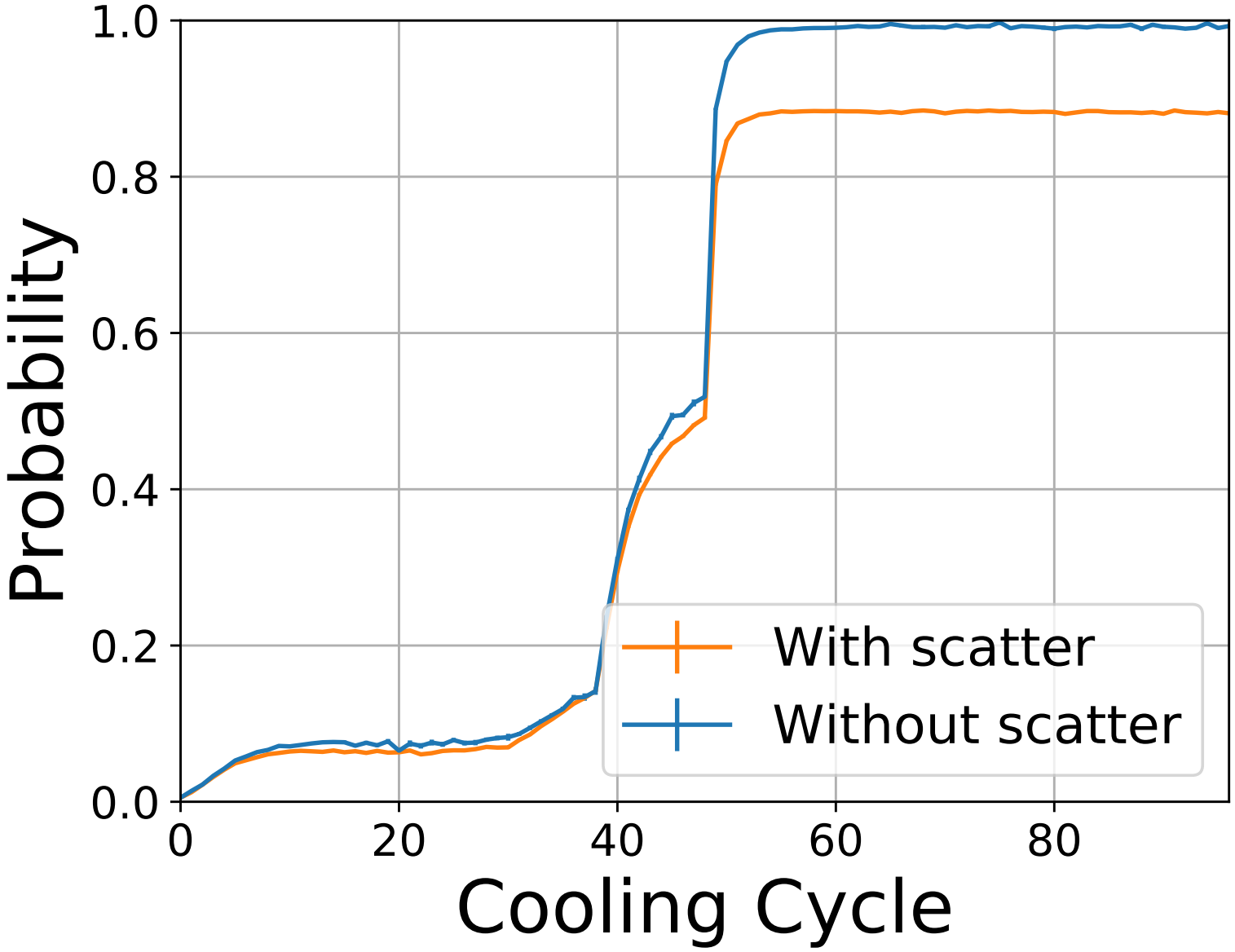
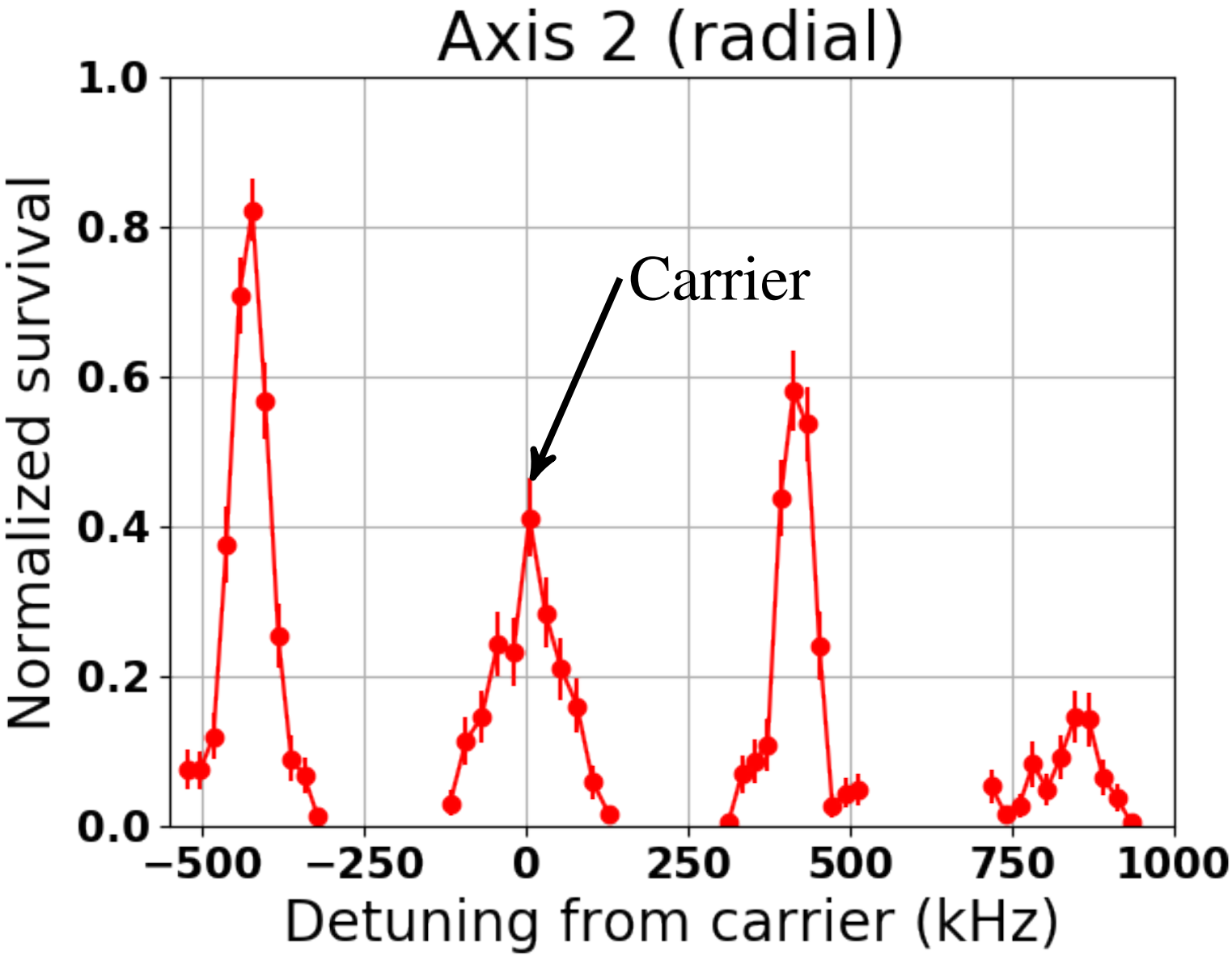


Raman sidebands



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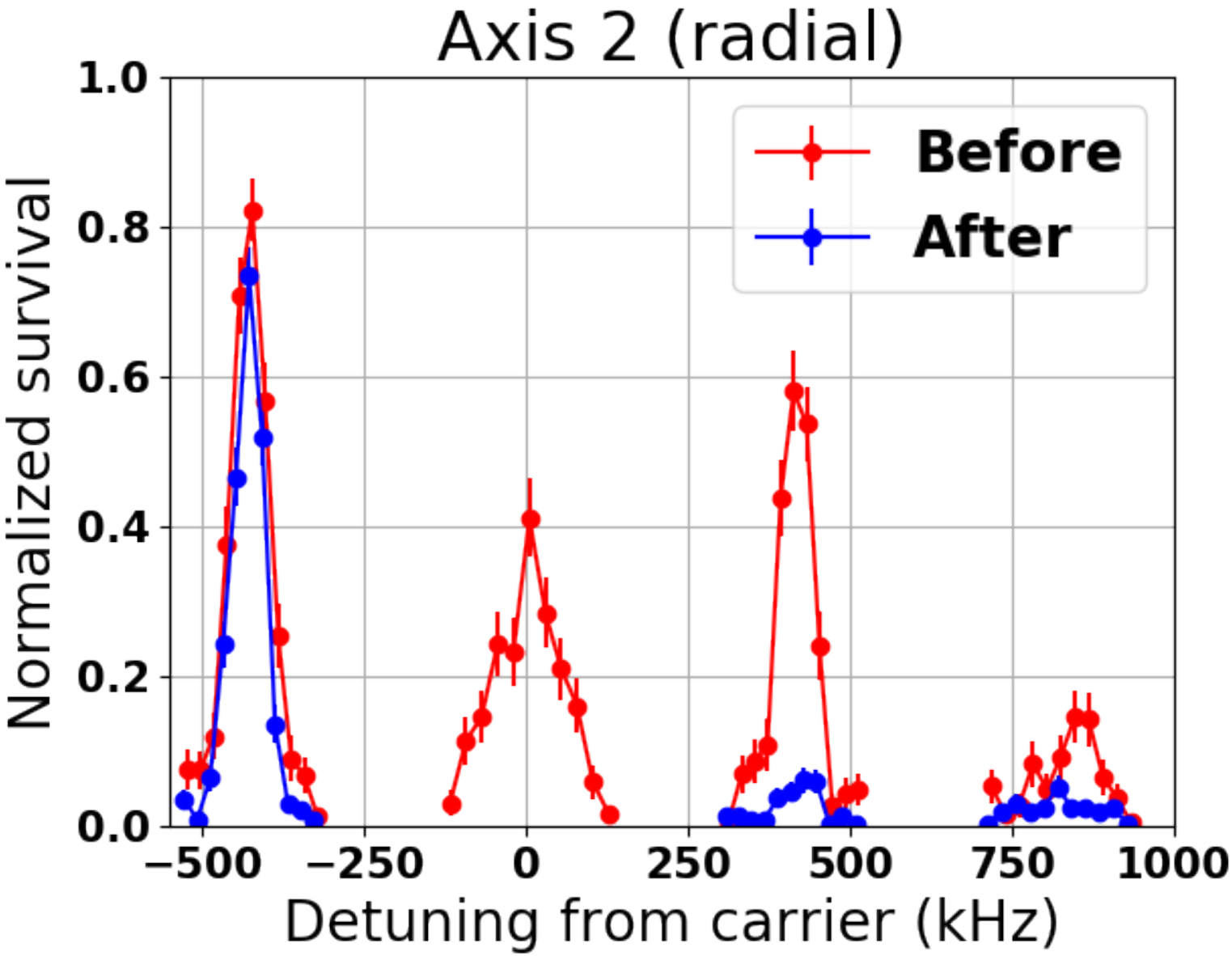

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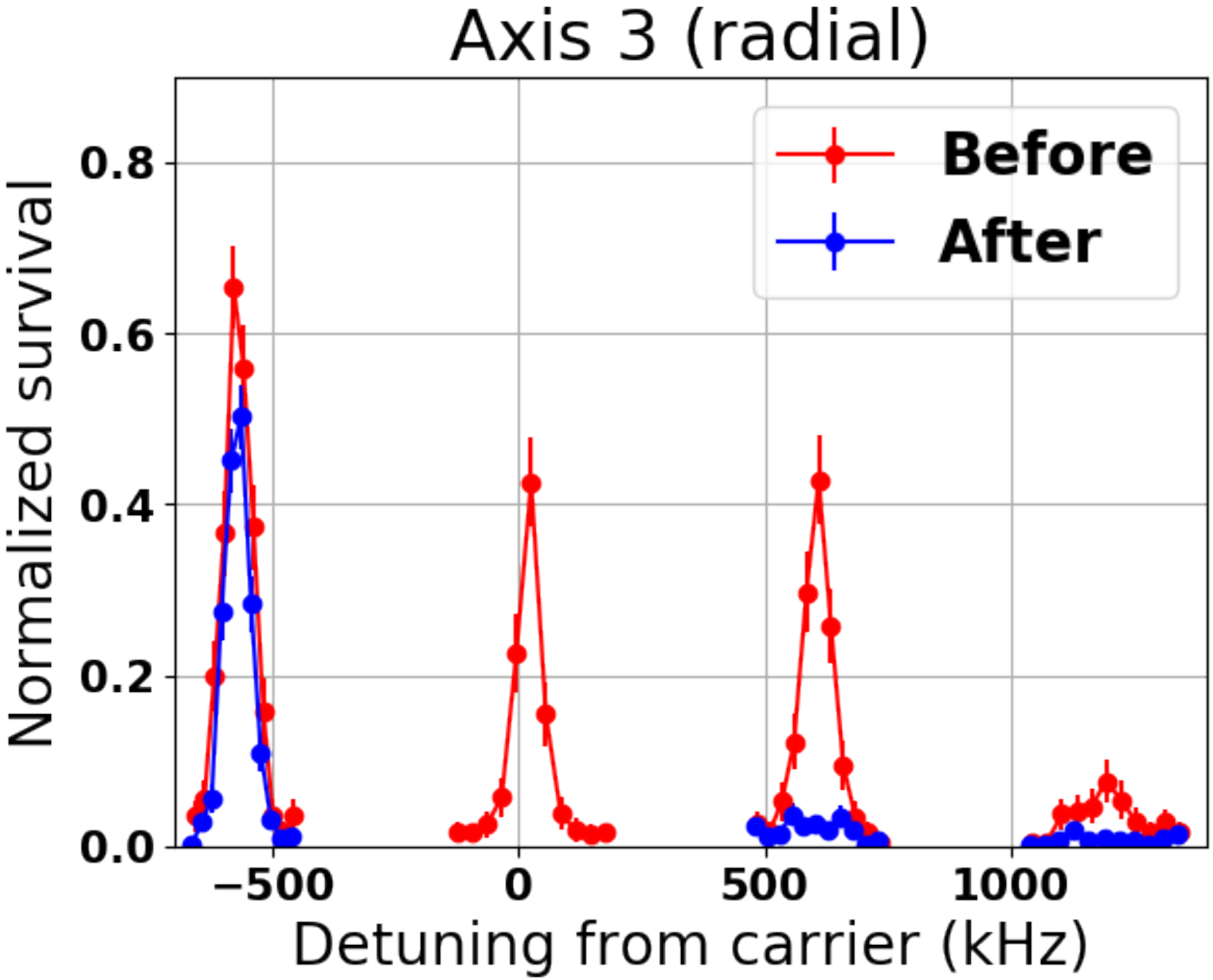
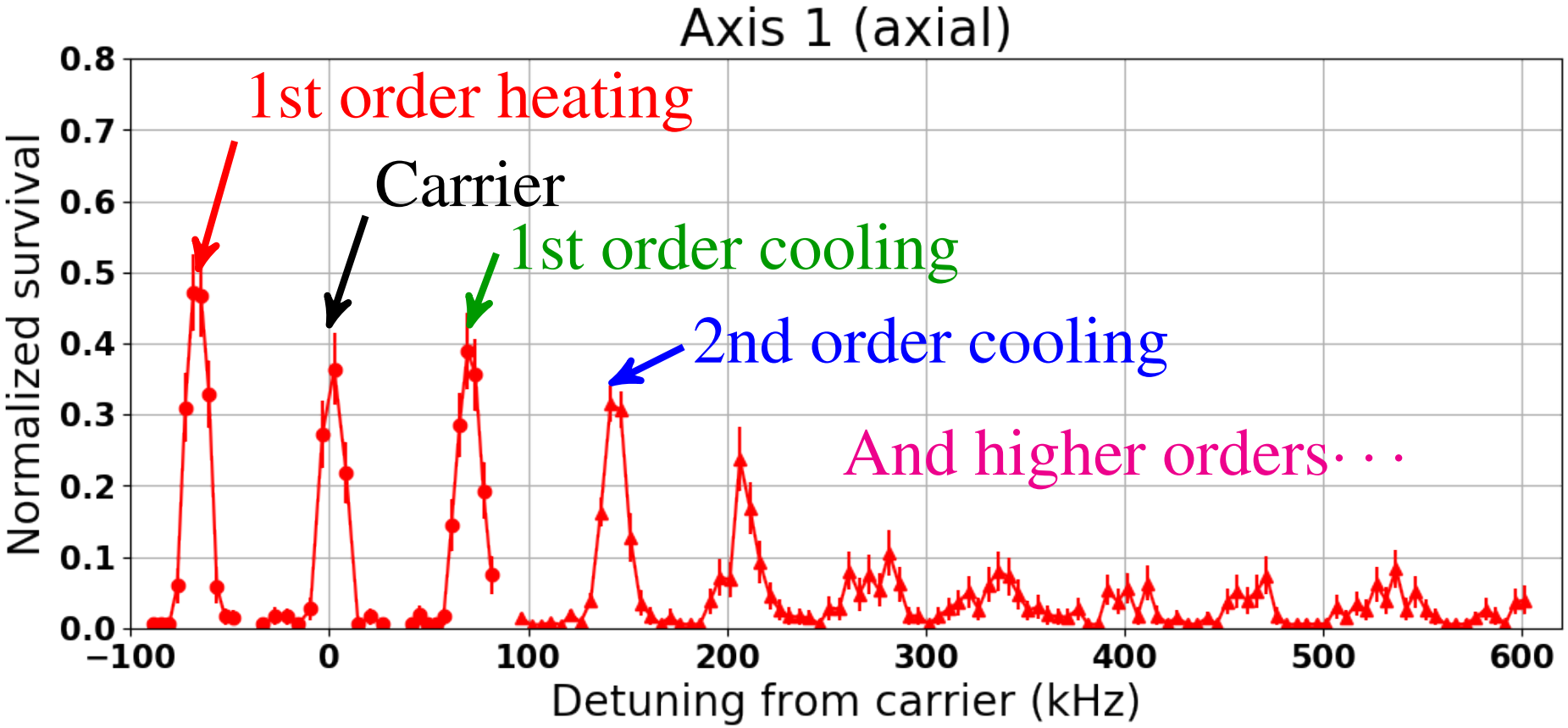
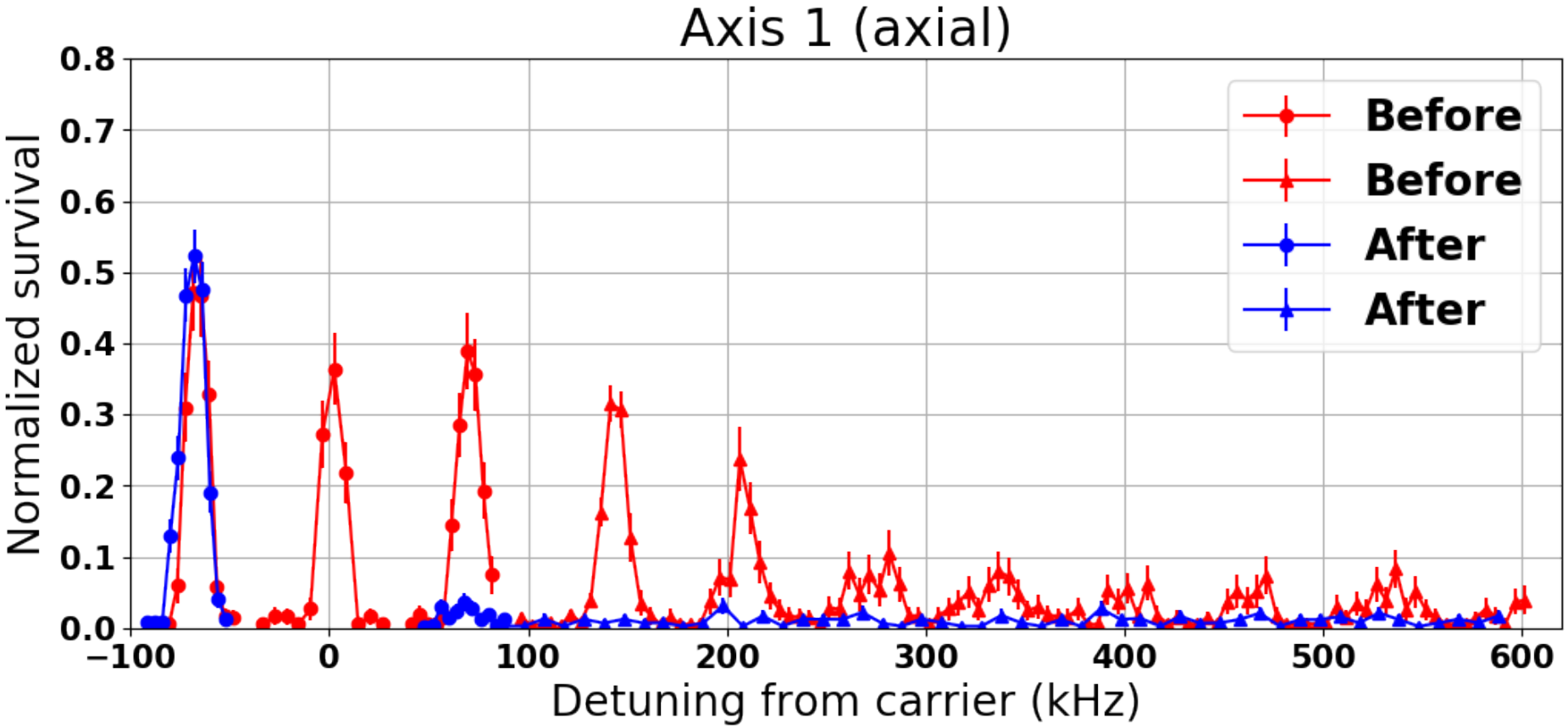


Raman sidebands

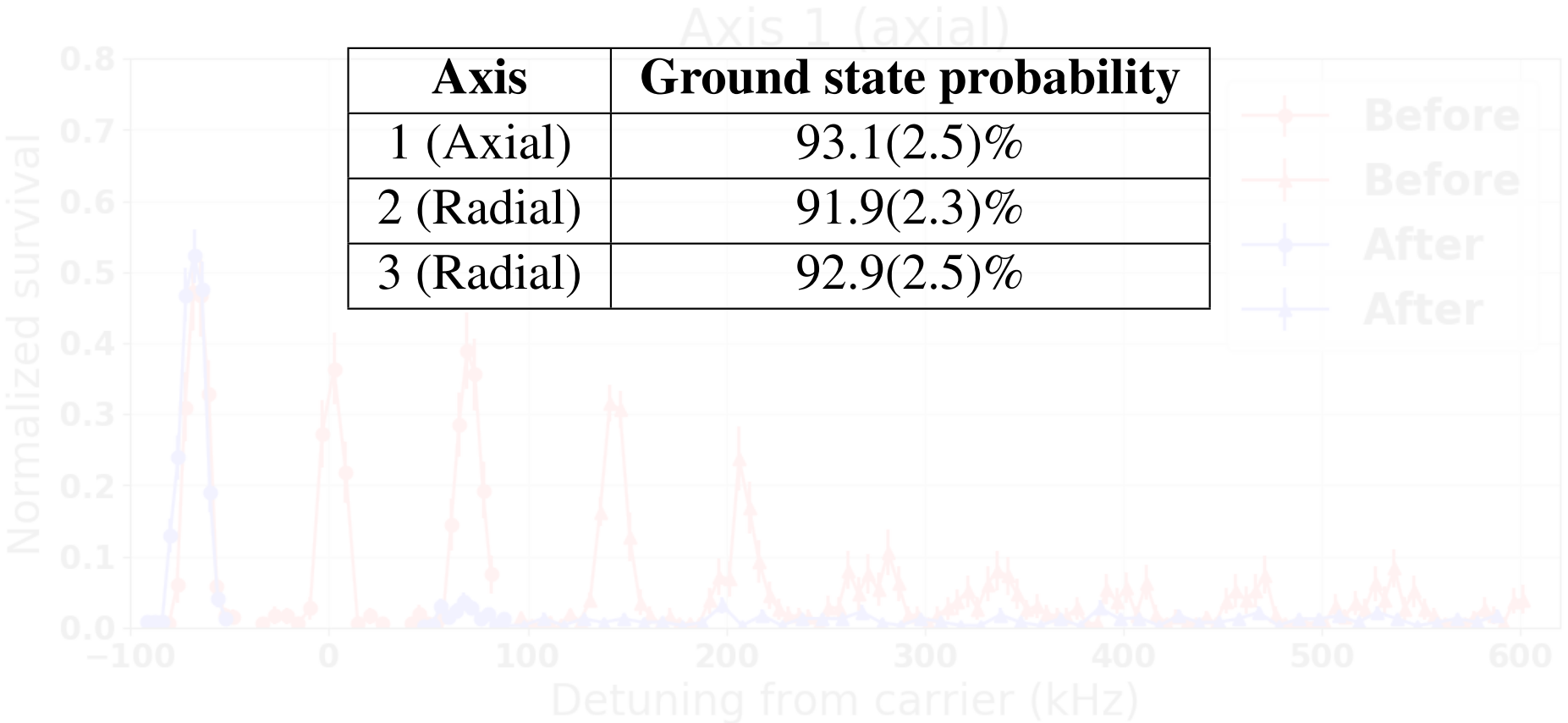


Raman sidebands



Raman sidebands

Axis	Ground state probability
1 (Axial)	93.1(2.5)%
2 (Radial)	91.9(2.3)%
3 (Radial)	92.9(2.5)%



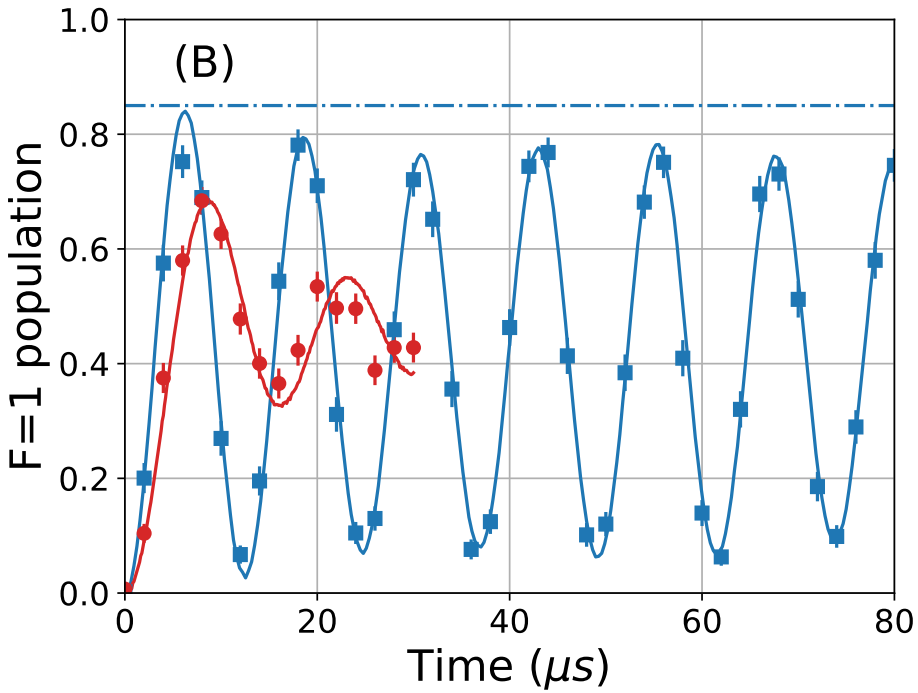
Raman sidebands

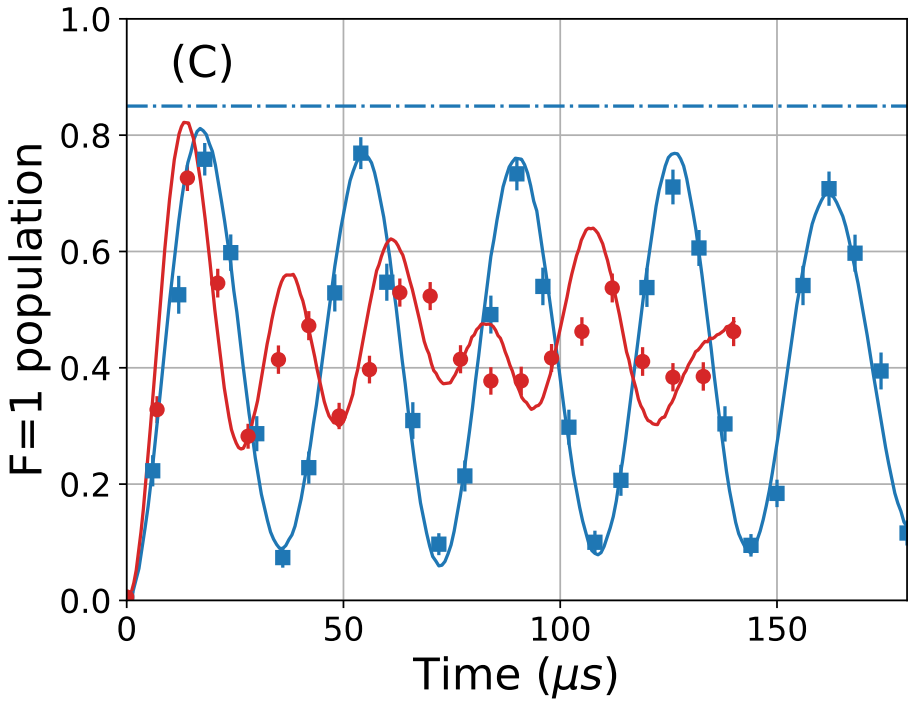
Axis	Ground state probability
1 (Axial)	93.1(2.5)%
2 (Radial)	91.9(2.3)%
3 (Radial)	92.9(2.5)%

3D ground state: 79.5(3.6)%
Loss after cooling: 15%

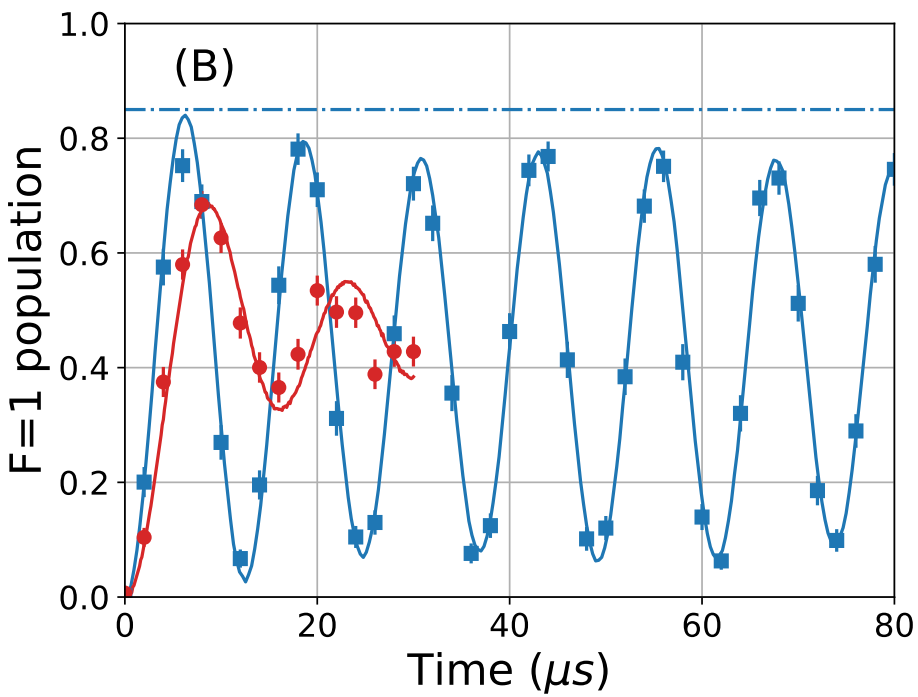
Total 3D ground state preparation fidelity: 67.6(3.1)%

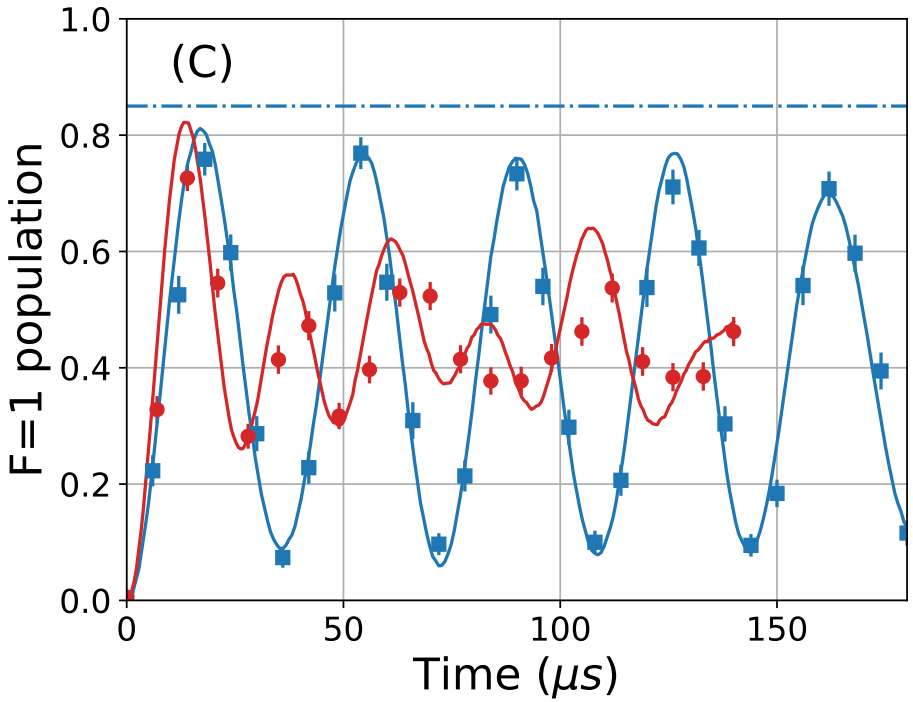
Rabi flopping (radial)





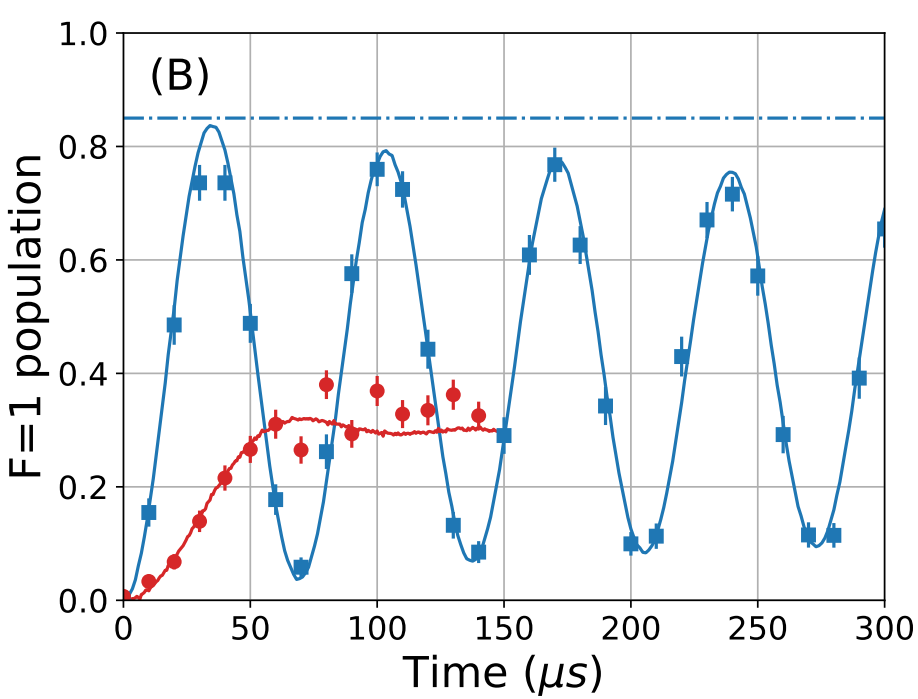
Rabi flopping (radial)

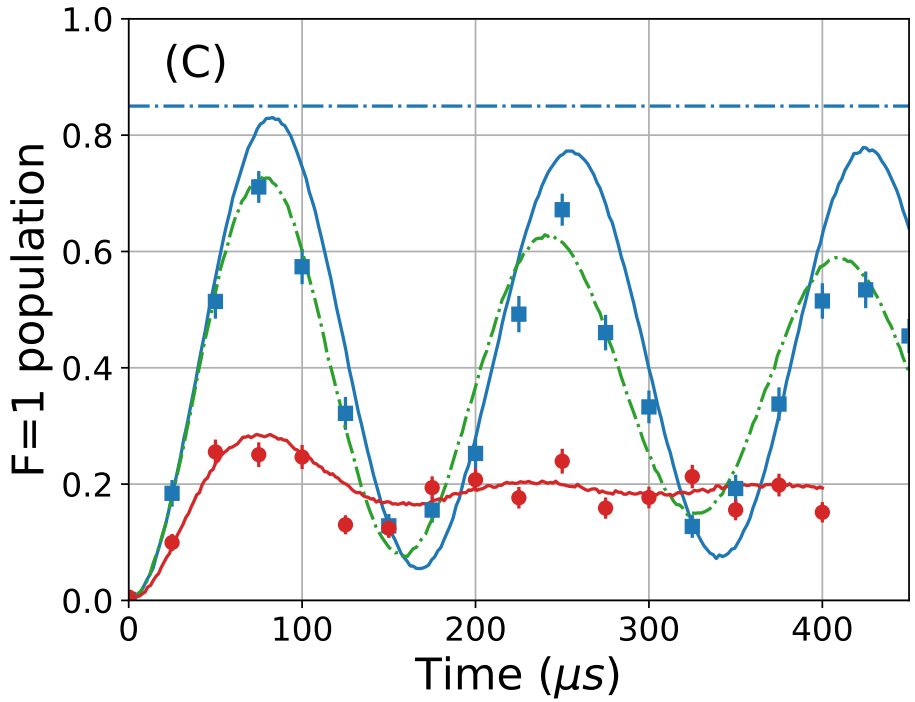




Good agreement in ground state probability between spectrum and Rabi flopping data.

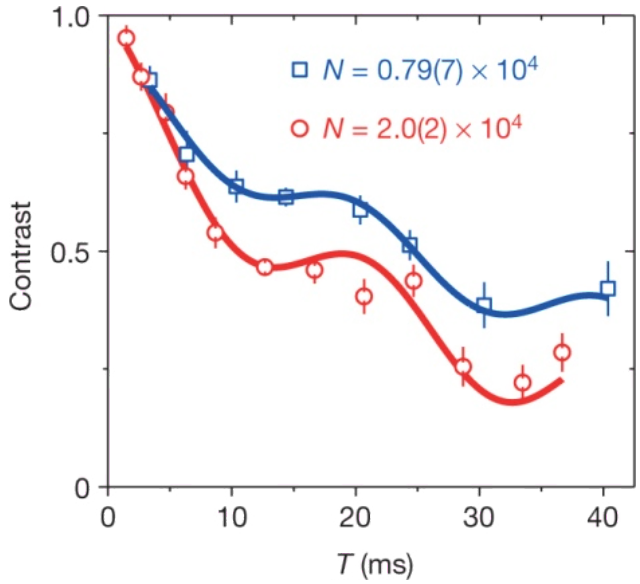
Rabi flopping (axial)

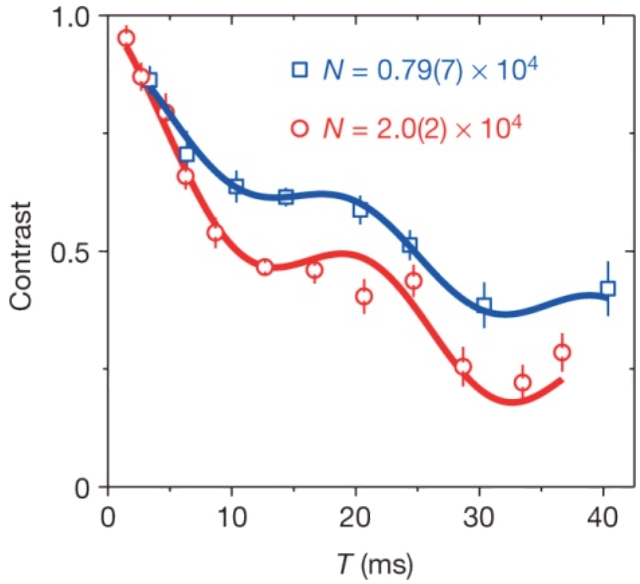


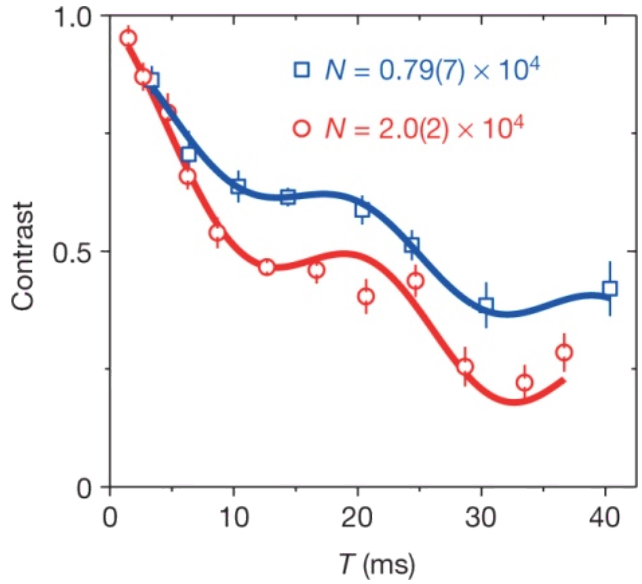


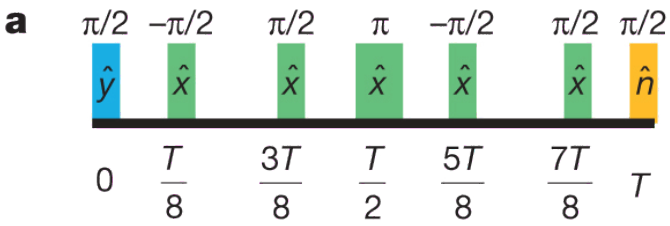
Decoherence caused by technical noise.
E.g. 1.5 mG of magnetic field noise.

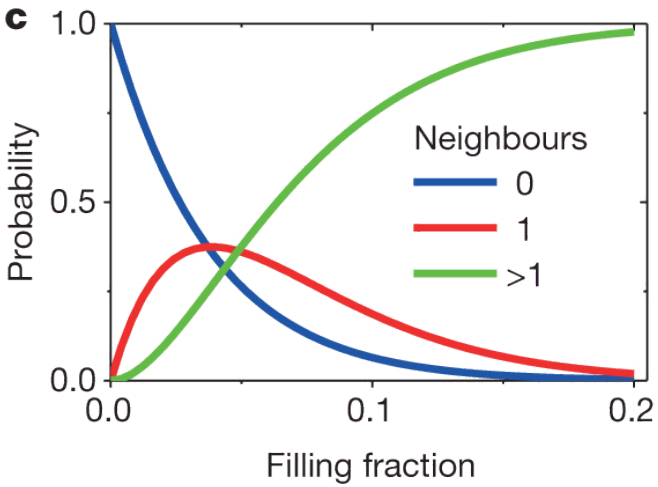
In progress

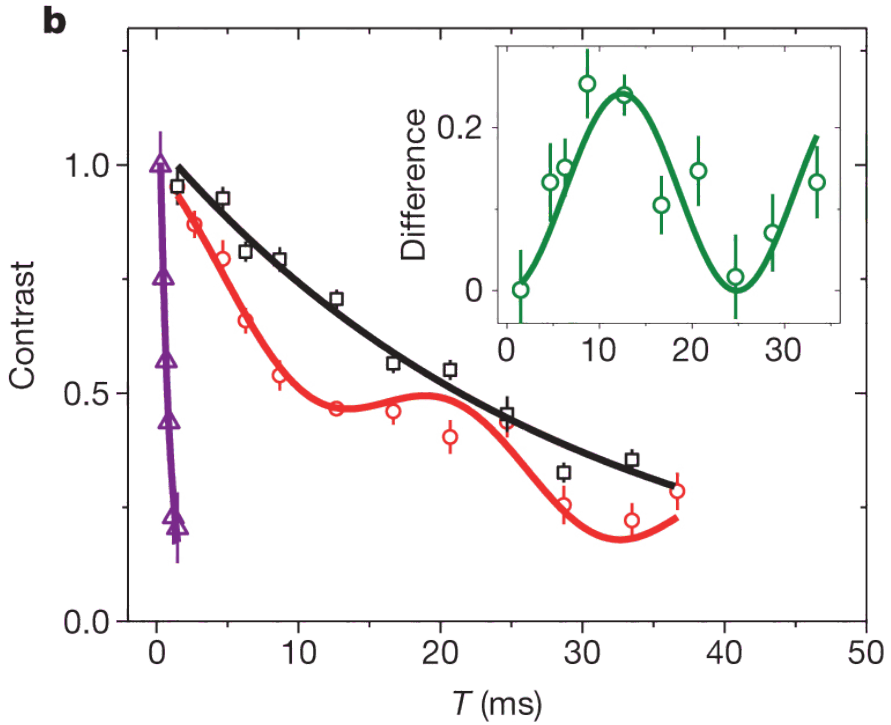

1.0
0.5
0
Contrast
0
10
20
30
40
T (ms)
N = 0.79(7) × 10^4
N = 2.0(2) × 10^4


1.0
0.5
0
Contrast
0
10
20
30
40
T (ms)
N = 0.79(7) × 10^4
N = 2.0(2) × 10^4


1.0
0.5
0
Contrast
$N = 0.79(7) \times 10^4$
$N = 2.0(2) \times 10^4$
0
10
20
30
40
T (ms)

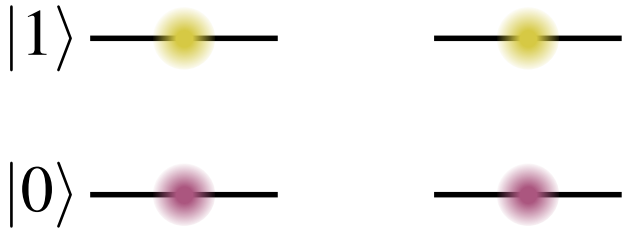

a
π/2
−π/2
π/2
π
−π/2
π/2
π/2
ŷ
x̂
x̂
x̂
x̂
x̂
n̂
0
T/8
3T/8
T/2
5T/8
7T/8
T


c
1.0
0.5
0.0
Probability
Neighbours
0
1
>1
0.0
0.1
0.2
Filling fraction


b
1.0
0.5
0.0
Contrast
Difference
0.2
0
0
10
20
30
40
50
T (ms)

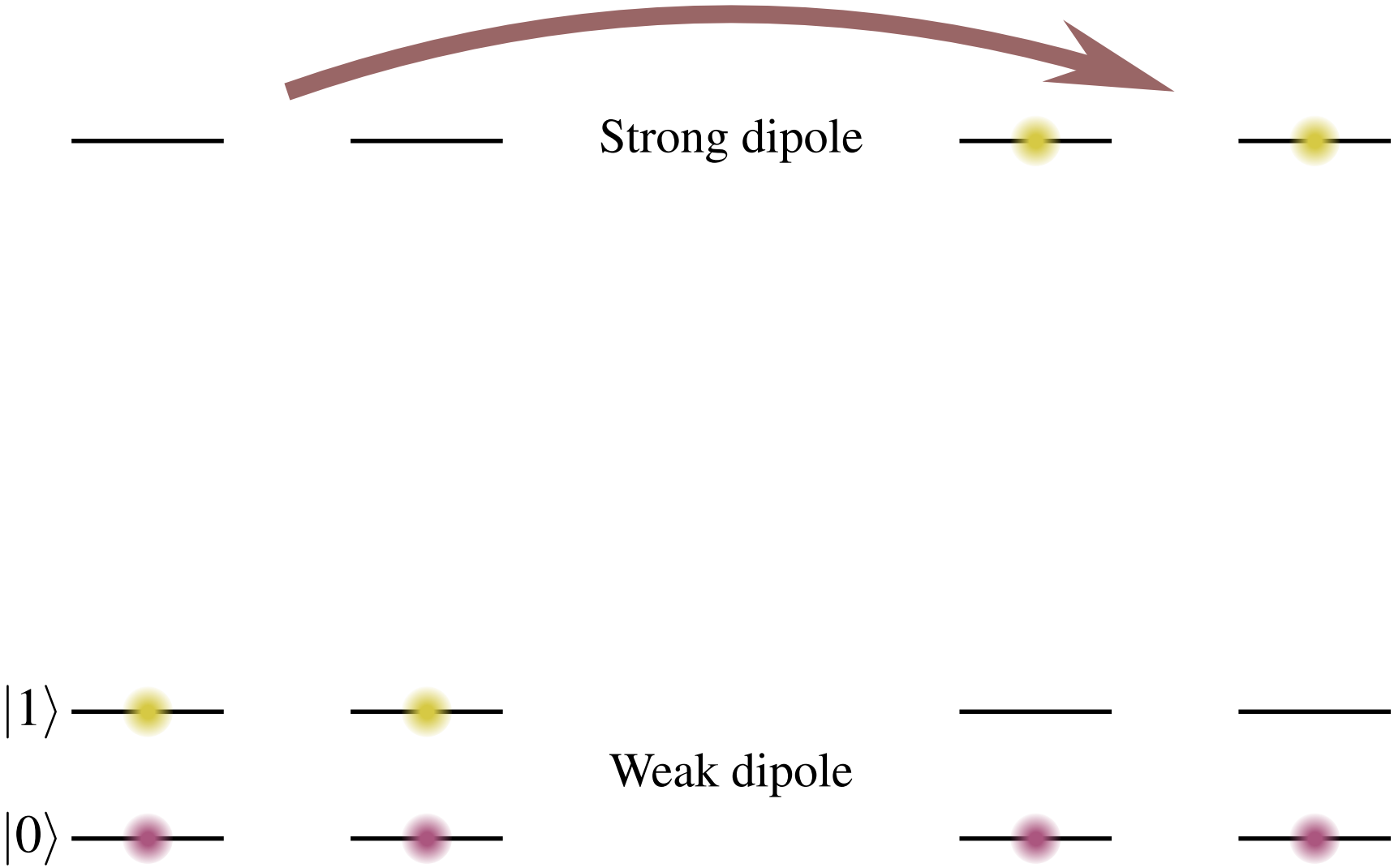
Quantum computation

Strong dipole

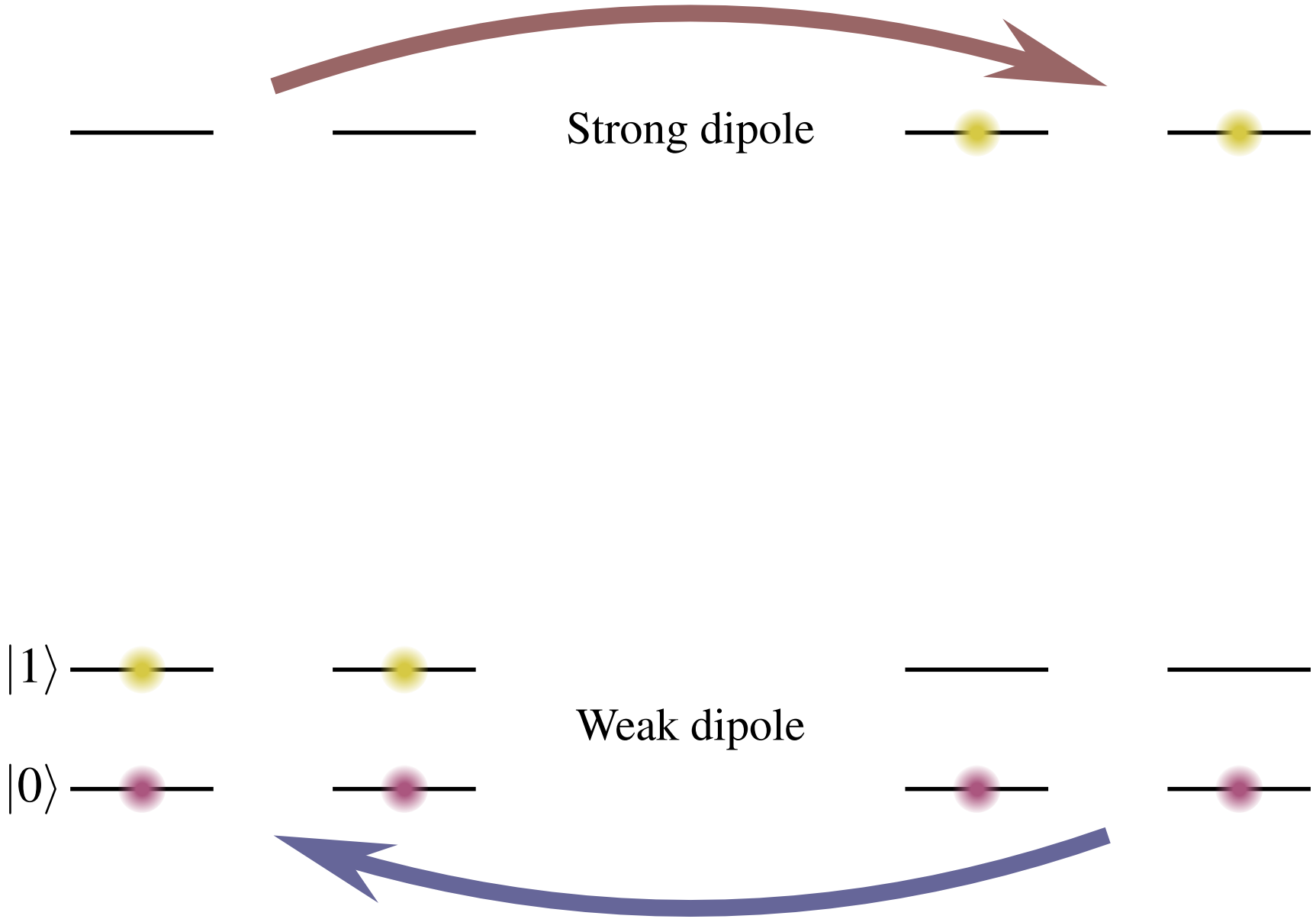


Weak dipole

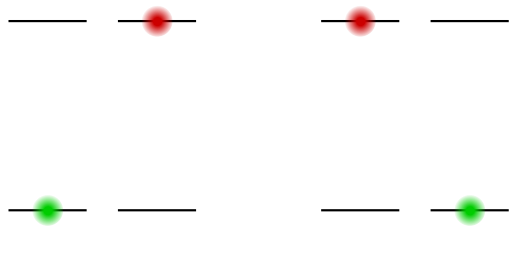
Quantum computation



Quantum computation

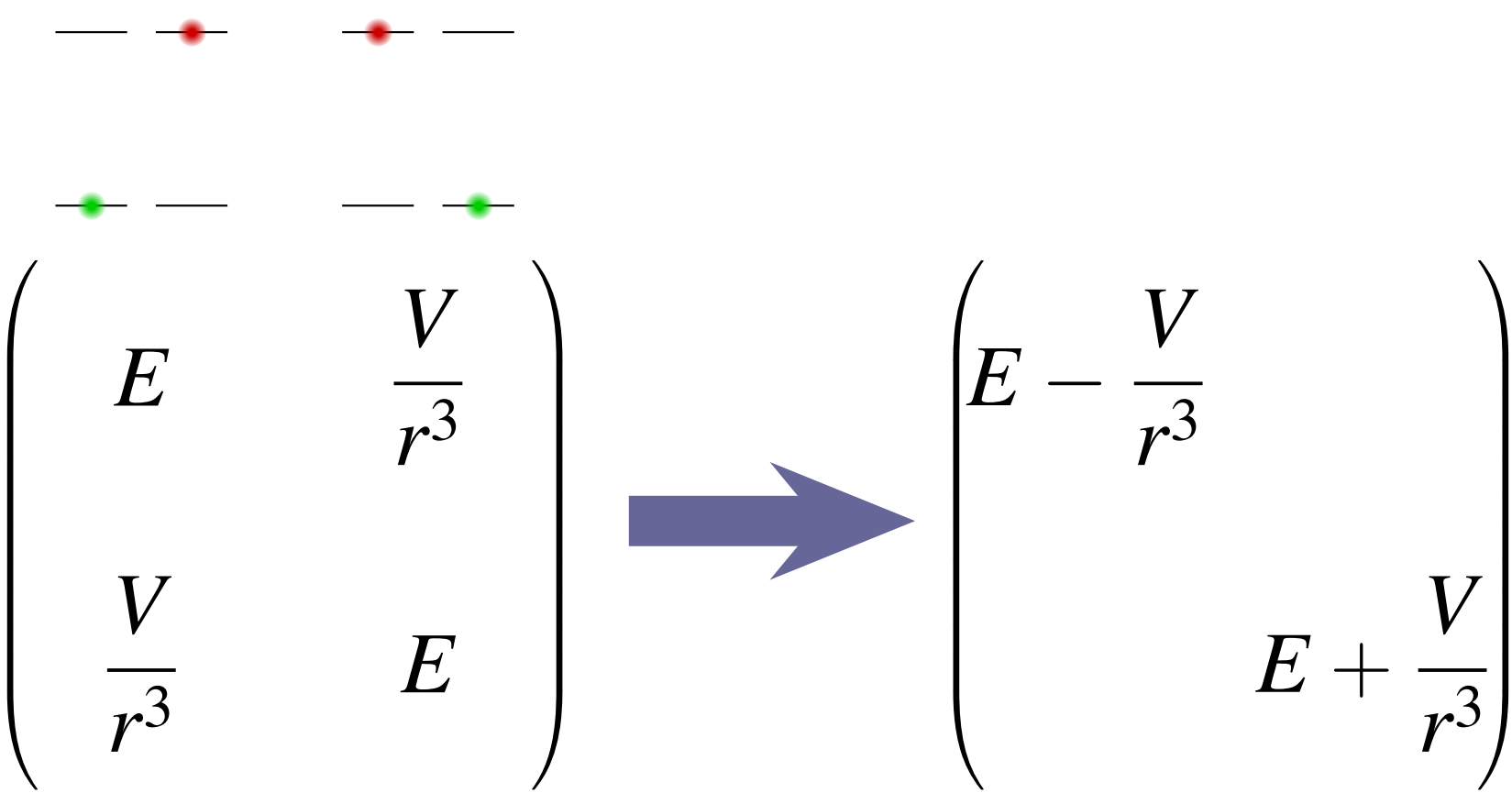


Quantum computation

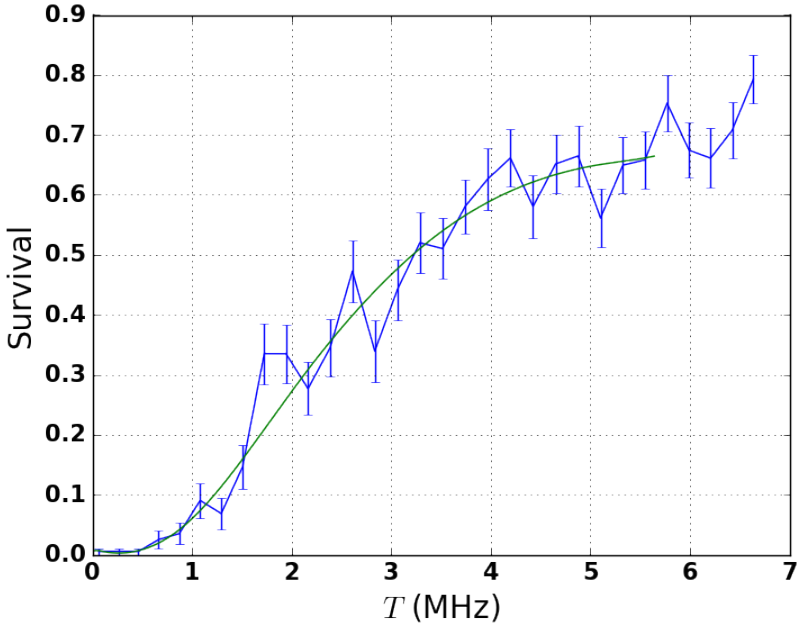


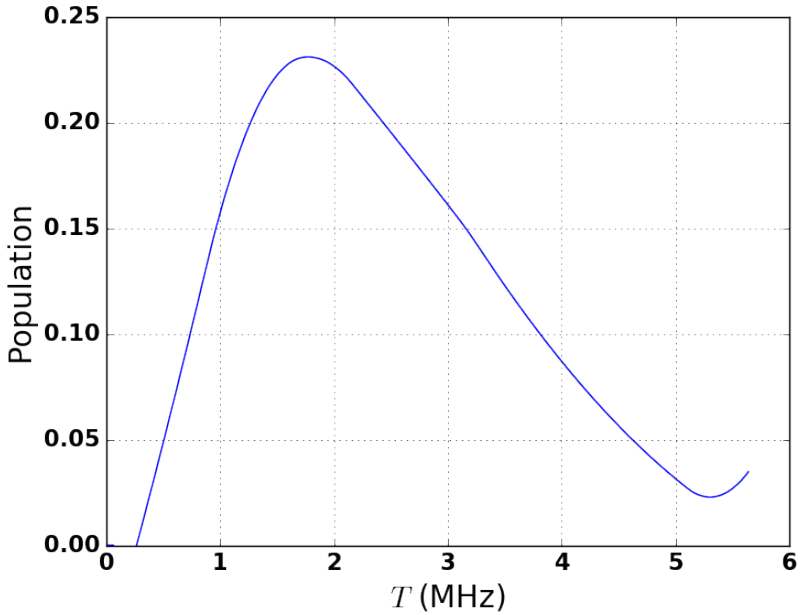
$$\begin{pmatrix} E & \frac{V}{r^3} \\ \frac{V}{r^3} & E \end{pmatrix}$$

Quantum computation

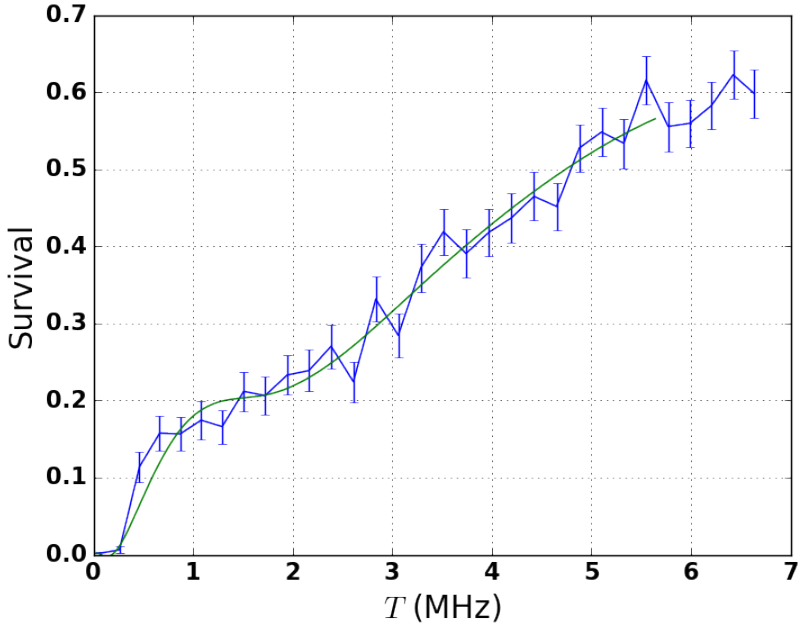


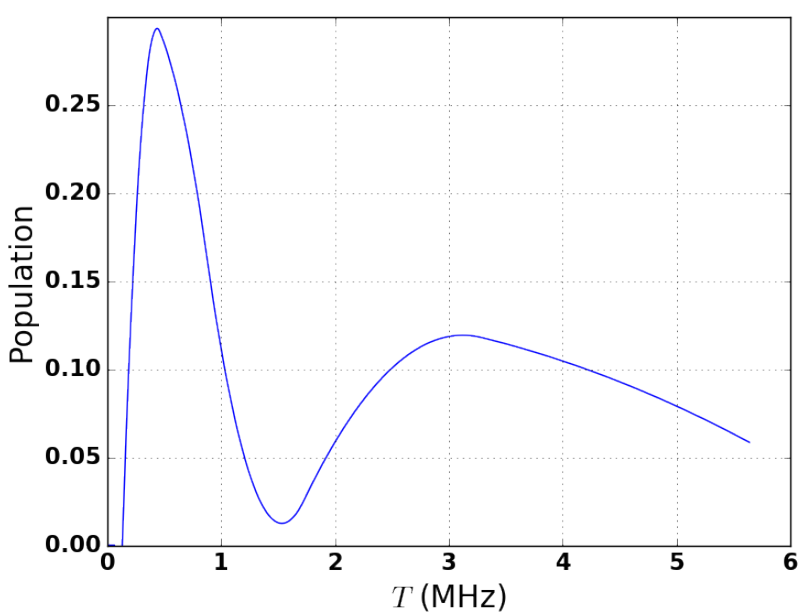
Before cooling



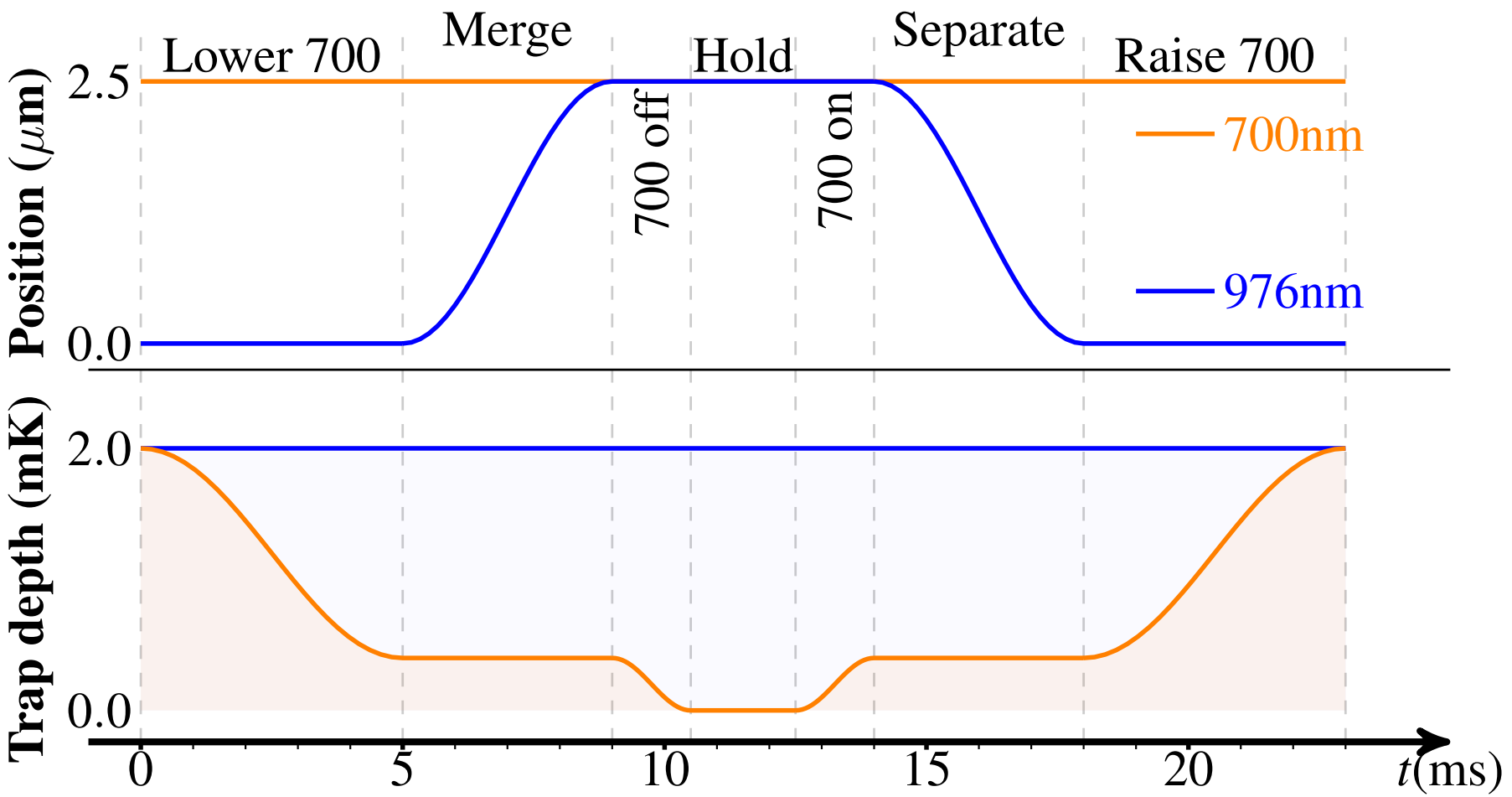


After cooling





Merge trap


Lower 700
Merge
Hold
Separate
Raise 700
700 off
700 on
700nm
976nm
Position (μm)
2.5
0.0
Trap depth (mK)
2.0
0.0
0
5
10
15
20
t(ms)